Report No.: RZA2010-0916

TESTING
No. L2264

ANSI C63.19

TEST REPORT

Product Name	cdma2000 Digital Mobile Phone
Model	HUAWEI C8600/HUAWEI M860
FCC ID	QISM860
Client	Huawei Technologies Co., Ltd.

TA Technology (Shanghai) Co., Ltd.

GENERAL SUMMARY

Product Name	cdma2000 Digital Mobile Phone	**Model**	HUAWEI C8600/HUAWEI M860
FCC ID	QISM860	**Report No.**	RZA2010-0916
Client	Huawei Technologies Co., Ltd.		
Manufacturer	Huawei Technologies Co., Ltd.		
Reference Standard(s)	**ANSI C63.19-2007:** American National Standard Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.		
Conclusion	This portable wireless equipment has been measured in all cases requested by the relevant standards. General Judgment: **M4 (RF Emission)** (Stamp) **Date of issue: June 24th, 2010**		
Comment	The test result only responds to the measured sample.		

Approved by 杨伟中 Yang Weizhong　　**Revised by** 凌敏宝 Ling Minbao　　**Performed by** 薛超峰 Xue Chaofeng

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1. General Information

1.1. Notes of the Test Report

TA Technology (Shanghai) Co., Ltd. guarantees the reliability of the data presented in this test report, which is the results of measurements and tests performed for the items under test on the date and under the conditions stated in this test report and is based on the knowledge and technical facilities available at TA Technology (Shanghai) Co., Ltd. at the time of execution of the test.

TA Technology (Shanghai) Co., Ltd. is liable to the client for the maintenance by its personnel of the confidentiality of all information related to the items under test and the results of the test. This report only refers to the item that has undergone the test.

This report standalone dose not constitute or imply by its own an approval of the product by the certification Bodies or competent Authorities. This report cannot be used partially or in full for publicity and/or promotional purposes without previous written approval of **TA Technology (Shanghai) Co., Ltd.** and the Accreditation Bodies, if it applies.

1.2. Testing Laboratory

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1.3. Applicant Information

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City:	Shenzhen
Postal Code:	518129
Country:	P.R. China
Contact:	Qiu Wei
Telephone:	0755-28780808
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1.4. Manufacturer Information

Company:	Huawei Technologies Co., Ltd.
Address:	Bantian, Longgang District
City:	Shenzhen
Postal Code:	518129
Country:	P.R. China
Telephone:	0755-28780808
Fax:	0755-28780808

1.5. Information of EUT

General Information

Device Type:	Portable Device		
Product Name:	cdma2000 Digital Mobile Phone		
SN:	2X2AA11051900058		
Antenna Type:	Internal Antenna		
Device Operating Configurations:			
Operating Mode(s):	CDMA Cellular (tested)		
	CDMA PCS (tested)		
	CDMA AWS (tested)		
Test Modulation:	QPSK		
Operating Frequency Range(s):	Band	Tx (MHz)	Rx (MHz)
	CDMA Cellular	824.7 ~ 848.31	869.7 ~ 893.31
	CDMA PCS	1851.25 ~ 1908.75	1931.25 ~ 1988.75
	CDMA AWS	1711.25 ~ 1752.5	2111.25 ~ 2152.5
Test Channel: (Low - Middle - High)	1013 - 384 - 777 (CDMA Cellular) (tested) 25 - 600 - 1175 (CDMA PCS) (tested) 25 - 450 - 850 (CDMA AWS) (tested)		
Power Class:	CDMA Cellular: Tested with Power Control All up bits		
	CDMA PCS: Tested with Power Control All up bits		
	CDMA AWS: Tested with Power Control All up bits		
Hardware Version:	HC1M860M		
Software Version:	M860V100R001C153B225		

Auxiliary Equipment Details

AE1:Battery

Model:	HB4F1
Manufacturer:	Huawei Technologies Co., Ltd.
SN:	SCC9A07HI4124145

AE2:Travel Adapter

Model:	HW-050100U1W
Manufacturer:	Huawei Technologies Co., Ltd.
SN:	HKAA50924234

Equipment Under Test (EUT) is a model of cdma2000 Digital Mobile Phone with internal antenna. The detail about Mobile phone, Lithium Battery and AC/DC Adapter is in chapter 1.5 in this report. SAR is tested for CDMA Cellular, CDMA PCS and CDMA AWS.

The sample under test was selected by the Client.

Components list please refer to documents of the manufacturer.

1.6. The Ambient Conditions during Test

Temperature	Min. = 18°C, Max. = 28 °C
Relative humidity	Min. = 0%, Max. = 80%
Ground system resistance	< 0.5 Ω
Ambient noise is checked and found very low and in compliance with requirement of standards. Reflection of surrounding objects is minimized and in compliance with requirement of standards.	

1.7. The Total M-rating of each tested band

Band	Rating
CDMA Cellular	**M4**
CDMA PCS	**M4**
CDMA AWS	**M4**

1.8. Test Date

The test is performed on June 22, 2010.

2. Test Information

2.1. Operational Conditions during Test

2.1.1. General Description of Test Procedures

The phone was tested in all normal configurations for the ear use. The EUT is mounted in the device holder equivalent as for classic dosimeter measurements. The acoustic output of the EUT shall coincide with the center point of the area formed by the dielectric wire and the middle bar of the arch's top frame The EUT shall be moved vertically upwards until it touches the frame. The fine adjustment is possible by sliding the complete. EUT holder on the yellow base plate of the Test Arch phantom. These test configurations are tested at the high, middle and low frequency channels of each applicable operating mode; for example, GSM, WCDMA (UMTS), CDMA and TDMA.

2.1.2. CDMA Test Configuration

A communication link is set up with a System Simulator (SS) by air link, and a call is established. The Absolute Radio Frequency Channel Number (ARFCN) are allocated to 1013, 384 and 777 respectively in the case of CDMA Cellular, allocated to 25, 600 and 1175 respectively in the case of CDMA PCS, allocated to 25, 450 and 850 respectively in the case of CDMA AWS,The EUT is commanded to operate at maximum transmitting power.

Test Parameter setup for maximum RF output power according to section 4.4.5 of 3GPP2.

Parameter	Units	Value
I or	dBm/1.23MHz	-104
PilotE c /I or	dB	-7
TrafficE c /I or	dB	-7.4

2.2. HAC RF Measurements System Configuration

2.2.1. HAC Measurement Set-up

These measurements are performed using the DASY4 automated dosimetric assessment system. It is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland. It consists of high precision robotics system (Stäubli), robot controller, Intel Core2 computer, near-field probe, probe alignment sensor. The robot is a six-axis industrial robot performing precise movements. Cell controller systems contain the power supply, robot controller, teach pendant (Joystick) and remote control, and are used to drive the robot motors. The Stäubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE) circuit performs the signal amplification; signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

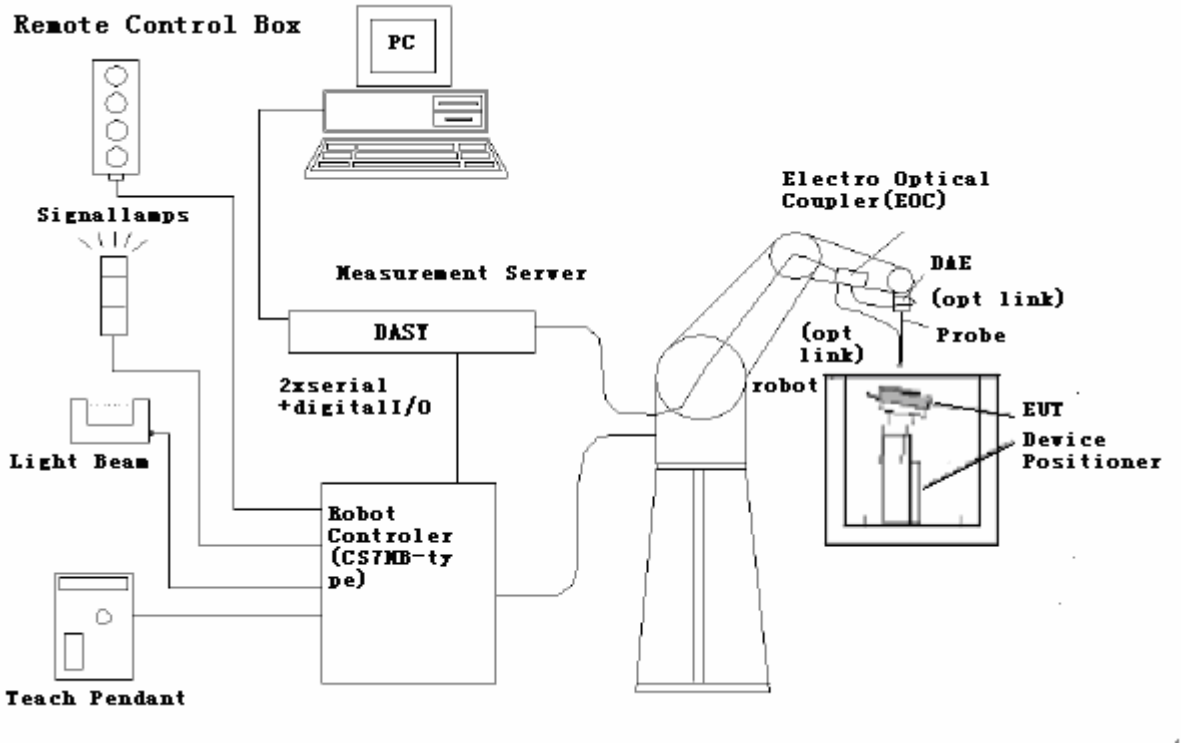


Figure 1 HAC Test Measurement Set-up

The DAE4 consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.

2.2.2. Probe System

The HAC measurements were conducted with the E-Field Probe ER3DV6 and the H-Field Probe H3DV6 (manufactured by SPEAG), designed in the classical triangular configuration and optimized for dosimetric evaluation.

E-Field Probe Description

Construction	One dipole parallel, two dipoles normal to probe axis Built-in shielding against static charges PEEK enclosure material
Calibration	In air from 100 MHz to 3.0 GHz (absolute accuracy ±6.0%, k=2)
Frequency	40 MHz to > 6 GHz (can be extended to < 20 MHz) Linearity: ± 0.2 dB (100 MHz to 3 GHz)
Directivity	± 0.2 dB in air (rotation around probe axis) ± 0.4 dB in air (rotation normal to probe axis)
Dynamic Range	2 V/m to > 1000 V/m; Linearity: ± 0.2 dB
Dimensions	Overall length: 330 mm (Tip: 16 mm) Tip diameter: 8 mm (Body: 12 mm) Distance from probe tip to dipole centers: 2.5 mm
Application	General near-field measurements up to 6 GHz Field component measurements Fast automatic scanning in phantoms

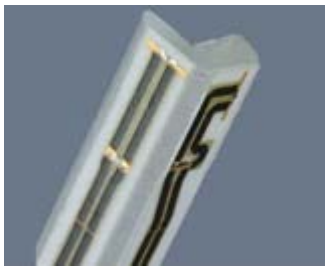


Figure 2 ER3DV6 E-field Probe

H-Field Probe Description

Construction	Three concentric loop sensors with 3.8 mm loop diameters Resistively loaded detector diodes for linear response Built-in shielding against static charges PEEK enclosure material (resistant to organic solvents, e.g., glycolether)
Frequency	200 MHz to 3 GHz (absolute accuracy ± 6.0%, k=2); Output linearized
Directivity	± 0.2 dB (spherical isotropy error)
Dynamic Range	10 mA/m to 2 A/m at 1 GHz
E-Field Interference	< 10% at 3 GHz (for plane wave)
Dimensions	Overall length: 330 mm (Tip: 40 mm) Tip diameter: 6 mm (Body: 12 mm) Distance from probe tip to dipole centers: 3 mm

Figure 3 H3DV6 H-field Probe

Application	General magnetic near-field measurements up to 3 GHz (in air or liquids) Field component measurements Surface current measurements Low interaction with the measured field

2.2.3. Test Arch Phantom & Phone Positioner

The Test Arch phantom should be positioned horizontally on a stable surface. Reference markings on the Phantom allow the complete setup of all predefined phantom positions and measurement grids by manually teaching three points in the robot. It enables easy and well defined positioning of the phone and validation dipoles as well as simple teaching of the robot (Dimensions: 370 x 370 x 370 mm).

The Device reference point is set for the EUT at 6.3 mm, the Grid reference point is on the upper surface at the origin of the coordinates, and the “user point \Height Check 0.5 mm” is 0.5mm above the center, allowing verication of the gap of 0.5mm while the probe is positioned there.

The Phone Positioner supports accurate and reliable positioning of any phone with effect on near field <±0.5 dB.

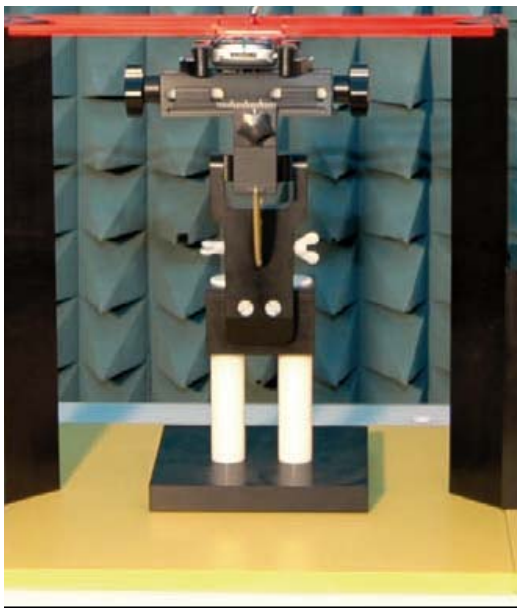


Figure 4 HAC Phantom & Device Holder

2.3. RF Test Procedures

The evaluation was performed with the following procedure:

1. Confirm proper operation of the field probe, probe measurement system and other instrumentation and the positioning system.
2. Position the WD in its intended test position. The gauge block can simplify this positioning. Note that a separate E-field and H-field gauge block will be needed if the center of the probe sensor elements is at different distances from the tip of the probe.
3. Configure the WD normal operation for maximum rated RF output power, at the desired channel and other operating parameters (e.g., test mode), as intended for the test.
4. The center sub-grid shall center on the center of the axial measurement point or the acoustic output, as appropriate. Locate the field probe at the initial test position in the 50 mm by 50 mm grid, which is contained in the measurement plane. If the field alignment method is used, align the probe for maximum field reception.
5. Record the reading.
6. Scan the entire 50 mm by 50 mm region in equally spaced increments and record the reading at each measurement point. The grid is 5 cm by 5 cm area that is divided into 9 evenly sized blocks or sub-grids.The distance between measurement points shall be sufficient to assure the identification of the maximum reading.
7. Identify the five contiguous sub-grids around the center sub-grid with the lowest maximum field strength readings. Thus the six areas to be used to determine the WD's highest emissions are identified and outlined for the final manual scan. Please note that a maximum of five blocks can be excluded for both E-field and H-field measurements for the WD output being measured. Stated another way, the center sub-grid and three others must be common to both the E-field and H-field measurements.
8. Identify the maximum field reading within the non-excluded sub-grids identified in Step 7.
9. Convert the maximum field strength reading identified in Step 8 to V/m or A/m, as appropriate. For probes which require a probe modulation factor, this conversion shall be done using the appropriate probe modulation factor and the calibration.
10. Repeat Step 1 through Step 10 for both the E-field and H-field measurements.
11. Compare this reading to the categories in ANSI C63.19 Clause 7 and record the resulting category. The lowest category number listed in 7.2, Table 7.4, or Table 7.5 obtained in Step 10 for either E- or H-field determines the M category for the audio coupling mode assessment. Record the WD category rating.

Figure 5 WD reference and plane for RF emission measurements

2.4. System Check

Validation Procedure

Place a dipole antenna meeting the requirements given in ANSI C63.19 D.5 in the position normally occupied by the WD. The dipole antenna serves as a known source for an electrical and magnetic output. Position the E-field and H-field probes so that:

The probes and their cables are parallel to the coaxial feed of the dipole antenna.
The probe cables and the coaxial feed of the dipole antenna approach the measurement area from opposite directions.
The center point of the probe element(s) are 10 mm from the closest surface of the dipole elements.
Validation was performed to verify that measured E-field and H-field values are within +/-25% from the target refenence values provided by the manufacturer. "Values within +/-25% are acceptable. Of which 12% is deviation and 13% is measurement uncertainty."

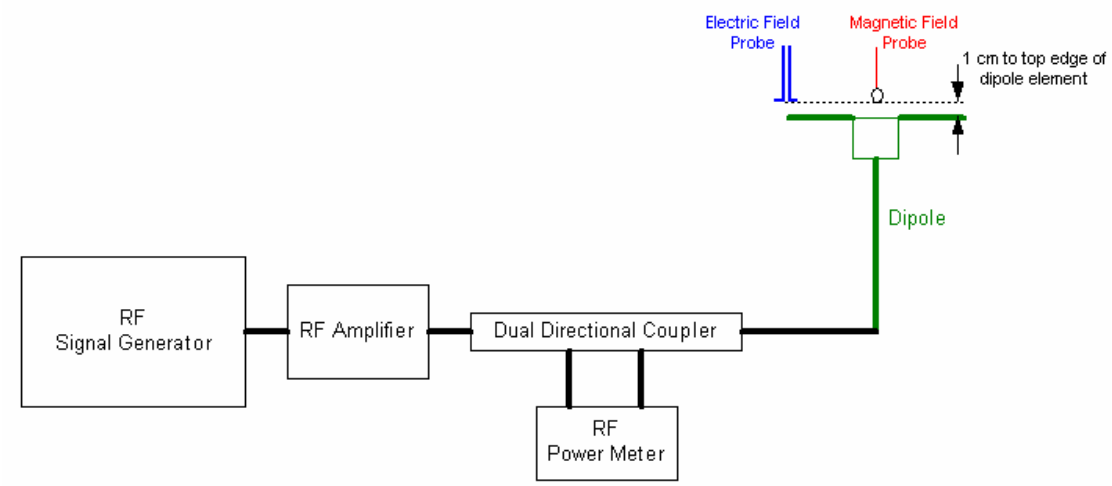


Figure 6 Dipole Validation Setup

Dipole Measurement Summary

E-Field Scan						
Mode	**Frequency (MHz)**	**Input Power (mW)**	**Measured[1] Value(V/m)**	**Target[2] Value(V/m)**	**Deviation[3] (%)**	**Test Date**
CW	835	100	149.2	170.7	12.60	June 22, 2010
CW	1880	100	131.4	142.9	8.05	June 22, 2010
F-Field Scan						
Mode	**Frequency (MHz)**	**Input Power (mW)**	**Measured Value(A/m)**	**Target Value(A/m)**	**Deviation (%)**	**Test Date**
CW	835	100	0.443	0.465	4.73	June 22, 2010
CW	1880	100	0.449	0.475	5.47	June 22, 2010

Notes: 1. please refer to the attachment for detailed measurement data and plot.
2. Target value is provided by SPEAD in the calibration certificate of specific dipoles.
3. Deviation (%) = 100 * (Target value minus Measured value) divided by Target value.

2.5. Probe Modulation Factor

The Probe Modulation Factor (PMF) is defined as the ratio of the field readings for a CW and a modulated signal with the equivalent Field Envelope Peak as defined in ANSI C63.19 (Chapter C.3.1).Calibration shall be made of the modulation response of the probe and its instrumentation chain. This Calibration shall be performed with the field probe, attached to the instrumentation that is to be used with it during the measurement. The response of the probe system to a CW field at the frequency(s) of interest is compared to its response to a modulated signal with equal peak amplitude. The field level of the test signals shall be more than 10dB above the ambient level and the noise floor of the instrumentation being used. The ratio of the CW reading to that taken with a modulated field shall be applied to the readings taken of modulated fields of the specified type.

Modulation Factor Test Procedure

This may be done using the following procedure:

1. Fix the field probe in a set location relative to a field generating device, such as the reference dipole antenna.
2. Illuminate the probe using the wireless device connected to the reference dipole with a test signal at the intended measurement frequency, Ensure there is sufficient field coupling between the probe and the antenna so the resulting reading is greater than 10 dB above the probe system noise floor but within the systems operating range.
3. Record the amplitude applied to the antenna during transmission and the field strength measured by the E-field probe located near the tip of the dipole antenna
4. Replace the wireless device with an RF signal generator producing an unmodulated CW signal and set to the wireless device operating frequency.
5. Set the amplitude of the unmodulated signal to equal that recorded from the wireless device.
6. Record the reading of the probe measurement system of the unmodulated signal.
7. The ratio, in linear units, of the probe reading in Step 6 to the reading in Step 3 is the E-field modulation factor. $PMF_E = E_{CW} / E_{mod}$ ($PMF_H = H_{CW} / H_{mod}$)
8. Repeat the previous steps using the H-field probe, except locate the probe at the center of the dipole.

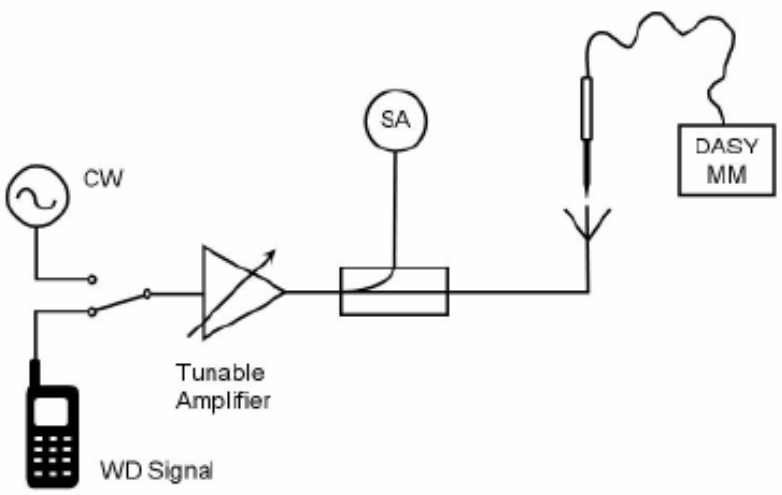


Figure Figure 7 Probe Modulation Factor Test Setup

PMF

Band	E-Field Probe Modulation Factor	H-Field Probe Modulation Factor
CDMA Cellular	1.0	1.0
CDMA PCS	1.0	1.0
CDMA AWS	1.0	1.0

2.6. Conducted Output Power Measurement

Summary

The DUT is tested using an E5515C communications tester as controller unit to set test channels and maximum output power to the DUT, as well as for measuring the conducted power. Conducted output power was measured using an integrated RF connector and attached RF cable. This result contains conducted output power for the EUT.

Conducted Power Results

CDMA Cellular (RC3)	**Conducted Power(dBm)**		
	Channel 1013	Channel 384	Channel 777
Before test	23.92	23.44	23.60
After test	23.91	23.46	23.62
CDMA Cellular (RC1)	**Conducted Power(dBm)**		
	Channel 1013	Channel 384	Channel 777
Before test	23.93	23.38	23.56
After test	23.93	23.41	23.55
CDMA Cellular EVDO (Rev.0)	**Conducted Power(dBm)**		
	Channel 1013	Channel 384	Channel 777
Before test	23.63	23.23	23.51
After test	23.61	23.20	23.48
CDMA Cellular EVDO (Rev.A)	**Conducted Power(dBm)**		
	Channel 1013	Channel 384	Channel 777
Before test	23.58	23.23	23.53
After test	23.62	23.20	23.55
CDMA PCS (RC3)	**Conducted Power(dBm)**		
	Channel 25	Channel 600	Channel 1175
Before test	25.12	23.86	24.20
After test	25.13	23.84	24.24
CDMA PCS (RC1)	**Conducted Power(dBm)**		
	Channel 25	Channel 600	Channel 1175
Before test	25.10	23.80	24.21
After test	25.07	23.83	24.22
CDMA PCS EVDO (Rev.0)	**Conducted Power(dBm)**		
	Channel 25	Channel 600	Channel 1175

Before test	24.11	23.33	23.51
After test	24.13	23.30	23.54
CDMA PCS EVDO (Rev.A)	**Conducted Power(dBm)**		
	Channel 25	Channel 600	Channel 1175
Before test	24.11	23.28	23.51
After test	24.11	23.24	23.48
CDMA AWS (RC3)	**Conducted Power(dBm)**		
	Channel 25	Channel 450	Channel 850
Before test	24.61	24.85	24.42
After test	24.65	24.86	24.46
CDMA AWS (RC1)	**Conducted Power(dBm)**		
	Channel 25	Channel 450	Channel 850
Before test	24.62	24.81	24.40
After test	24.65	24.85	24.37
CDMA AWS EVDO (Rev.0)	**Conducted Power(dBm)**		
	Channel 25	Channel 450	Channel 850
Before test	24.03	24.11	23.56
After test	24.01	24.08	23.54
CDMA AWS EVDO (Rev.A)	**Conducted Power(dBm)**		
	Channel 25	Channel 450	Channel 850
Before test	24.03	24.11	23.50
After test	24.03	24.10	23.53

3. Test Results

3.1. ANSI C63.19-2007 Limits

Category		Telephone RF parameters < 960 MHz			
Near field	**AWF**	**E-field emissions**		**H-field emissions**	
Category M1/T1	0	631.0 to 1122.0	V/m	1.91 to 3.39	A/m
	–5	473.2 to 841.4	V/m	1.43 to 2.54	A/m
Category M2/T2	0	354.8 to 631.0	V/m	1.07 to 1.91	A/m
	–5	266.1 to 473.2	V/m	0.80 to 1.43	A/m
Category M3/T3	0	199.5 to 354.8	V/m	0.60 to 1.07	A/m
	–5	149.6 to 266.1	V/m	0.45 to 0.80	A/m
Category M4/T4	0	< 199.5	V/m	< 0.60	A/m
	–5	< 149.6	V/m	< 0.45	A/m
Category		**Telephone RF parameters > 960 MHz**			
Near field	**AWF**	**E-field emissions**		**H-field emissions**	
Category M1/T1	0	199.5 to 354.8	V/m	0.60 to 1.07	A/m
	–5	149.6 to 266.1	V/m	0.45 to 0.80	A/m
Category M2/T2	0	112.2 to 199.5	V/m	0.34 to 0.60	A/m
	–5	84.1 to 149.6	V/m	0.25 to 0.45	A/m
Category M3/T3	0	63.1 to 112.2	V/m	0.19 to 0.34	A/m
	–5	47.3 to 84.1	V/m	0.14 to 0.25	A/m
Category M4/T4	0	< 63.1	V/m	< 0.19	A/m
	–5	< 47.3	V/m	< 0.14	A/m

3.2. Summary Test Results

CDMA Cellular Results

E-Field					
Channel	**Frequency (MHz)**	**Peak Field (V/m)**	**Power Drift (dB)**	**Rating**	**Graph Results**
777	848.31	77.500	-0.001	M4	Figure 12
384	836.52	72.100	-0.010	M4	Figure 13
1013	824.70	62.400	-0.004	M4	Figure 14
H-Field					
Channel	**Frequency (MHz)**	**Peak Field (A/m)**	**Power Drift (dB)**	**Rating**	**Graph Results**
777	848.31	0.116	0.055	M4	Figure 15
384	836.52	0.107	-0.055	M4	Figure 16
1013	824.70	0.090	0.133	M4	Figure 17

CDMA PCS Results

E-Field					
Channel	**Frequency (MHz)**	**Peak Field (V/m)**	**Power Drift (dB)**	**Rating**	**Graph Results**
1175	1908.75	23.800	-0.122	M4	Figure 18
600	1880	21.700	-0.125	M4	Figure 19
25	1851.25	20.300	-0.012	M4	Figure 20
H-Field					
Channel	**Frequency (MHz)**	**Peak Field (A/m)**	**Power Drift (dB)**	**Rating**	**Graph Results**
1175	1908.75	0.060	-0.054	M4	Figure 21
600	1880	0.063	-0.161	M4	Figure 22
25	1851.25	0.065	0.092	M4	Figure 23

CDMA AWS Results

E-Field					
Channel	**Frequency (MHz)**	**Peak Field (V/m)**	**Power Drift (dB)**	**Rating**	**Graph Results**
850	1752.5	22.000	0.041	M4	Figure 24
450	1732.5	24.400	-0.005	M4	Figure 25
25	1711.25	25.500	0.061	M4	Figure 26
H-Field					
Channel	**Frequency (MHz)**	**Peak Field (A/m)**	**Power Drift (dB)**	**Rating**	**Graph Results**
850	1752.5	0.063	-0.009	M4	Figure 27
450	1732.5	0.071	-0.012	M4	Figure 28
25	1711.25	0.077	-0.132	M4	Figure 29

4. Measurement Uncertainty

No.	Error source	Type	Uncertainty Value (%)	Prob. Dist.	k	c_i/E	c_i\H	Standard Uncertainty (%) u_i' (%) E	Standard Uncertainty (%) u_i' (%) H	Degree of freedom V_{eff} or v_i
Measurement System										
1	Probe Calibration	B	5.	N	1	1	1	5.1	5.1	∞
2	Axial Isotropy	B	4.7	R	$\sqrt{3}$	1	1	2.7	2.7	∞
3	Sensor Displacement	B	16.5	R	$\sqrt{3}$	1	0.145	9.5	1.4	∞
4	Boundary Effects	B	2.4	R	$\sqrt{3}$	1	1	1.4	1.4	∞
5	Linearity	B	4.7	R	$\sqrt{3}$	1	1	2.7	2.7	∞
6	Scaling to Peak Envelope Power	B	2.0	R	$\sqrt{3}$	1	1	1.2	1.2	∞
7	System Detection Limit	B	1.0	R	$\sqrt{3}$	1	1	0.6	0.6	∞
8	Readout Electronics	B	0.3	N	1	1	1	0.3	0.3	∞
9	Response Time	B	0.8	R	$\sqrt{3}$	1	1	0.5	0.5	∞
10	Integration Time	B	2.6	R	$\sqrt{3}$	1	1	1.5	1.5	∞
11	RF Ambient Conditions	B	3.0	R	$\sqrt{3}$	1	1	1.7	1.7	∞
12	RF Reflections	B	12.0	R	$\sqrt{3}$	1	1	6.9	6.9	∞
13	Probe Positioner	B	1.2	R	$\sqrt{3}$	1	0.67	0.7	0.5	∞
14	Probe Positioning	A	4.7	R	$\sqrt{3}$	1	0.67	2.7	1.8	∞
15	Extra. And Interpolation	B	1.0	R	$\sqrt{3}$	1	1	0.6	0.6	∞
Test Sample Related										
16	Device Positioning Vertical	B	4.7	R	$\sqrt{3}$	1	0.67	2.7	1.8	∞
17	Device Positioning Lateral	B	1.0	R	$\sqrt{3}$	1	1	0.6	0.6	∞
18	Device Holder and Phantom	B	2.4	R	$\sqrt{3}$	1	1	1.4	1.4	∞

19	Power Drift	B	5.0	R	$\sqrt{3}$	1	1	2.9	2.9	∞
Phantom and Setup related										
20s	Phantom Thickness	B	2.4	R	$\sqrt{3}$	1	0.67	1.4	0.9	∞
Combined standard uncertainty(%)								14.7	10.9	
Expanded uncertainty (confidence interval of 95 %)		$u_e = 2u_c$		N	k=2			29.4	21.8	

5. Main Test Instruments

No.	Name	Type	Serial Number	Calibration Date	Valid Period
01	Power meter	Agilent E4417A	GB41291714	March 13, 2010	One year
02	Power sensor	Agilent 8481H	MY41091316	March 26, 2010	One year
03	Signal Generator	HP 8341B	2730A00804	September 13, 2009	One year
04	Amplifier	IXA-020	0401	No Calibration Requested	
05	BTS	E5515C	MY48360988	December 4, 2009	One year
06	E-Field Probe	ER3DV6	2428	October 20, 2009	One year
07	H-Field Probe	H3DV6	6260	October 20, 2009	One year
08	DAE	DAE4	871	November 11, 2009	One year
09	Validation Kit 835MHz	CD835V3	1149	January 12, 2010	One year
10	Validation Kit 1880MHz	CD1880V3	1135	January 13, 2010	One year

*******END OF REPORT BODY*******

ANNEX A: System Check Results

HAC_System Performance Check at 835MHz_E

DUT: Dipole 835 MHz; Type: CD835V3; SN:1149

Date/Time: 6/22/2010 1:17:32 AM

Communication System: CW; Frequency: 835 MHz;Duty Cycle: 1:1

Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1000 kg/m^3

Ambient Temperature:22.3 ℃ Liqiud Temperature: 21.5℃

Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 149.2 V/m

Probe Modulation Factor = 1.00

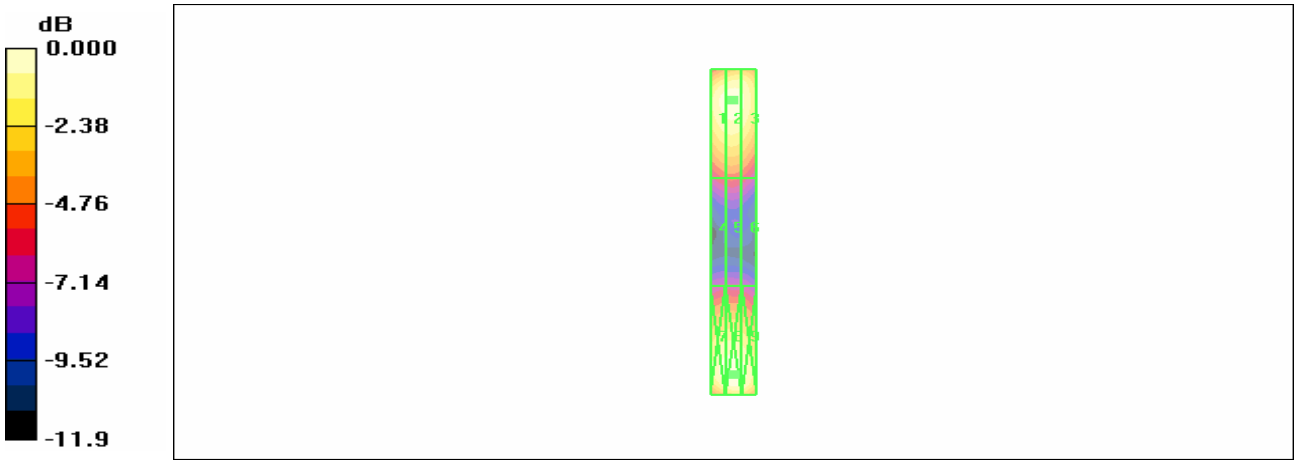
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 100.7 V/m; Power Drift = -0.066 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **147.0 M4**	Grid 2 **149.2 M4**	Grid 3 **143.9 M4**
Grid 4 **83.4 M4**	Grid 5 **85.0 M4**	Grid 6 **81.1 M4**
Grid 7 **148.8 M4**	Grid 8 **154.0 M4**	Grid 9 **148.9 M4**



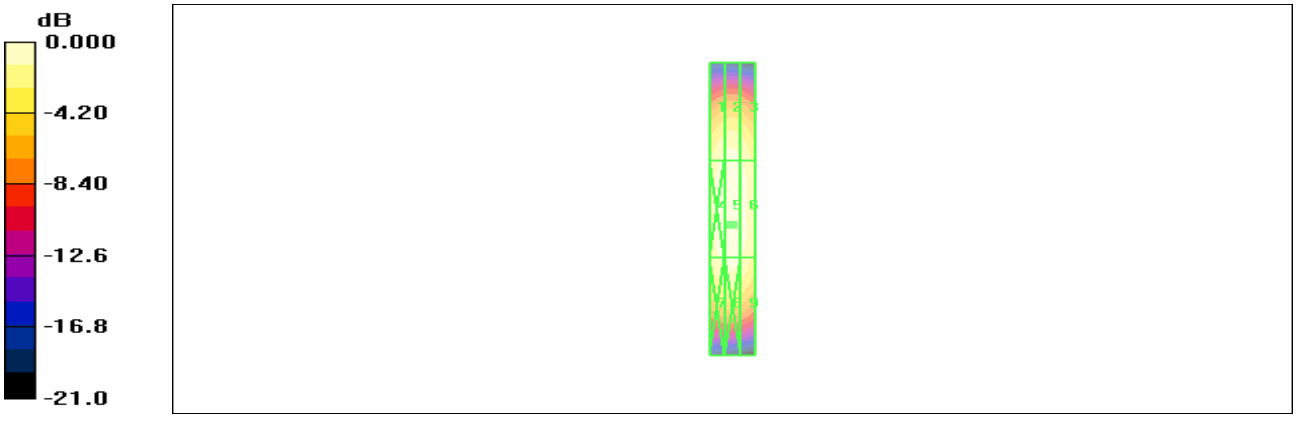
0 dB = 154.0V/m

Figure 8 System Performance Check 835MHz_E

HAC_System Performance Check at 835MHz_H
DUT: Dipole 835 MHz; Type: CD835V3; SN: 1149
Date/Time: 6/22/2010 2:09:58 AM
Communication System: CW; Frequency: 835 MHz;Duty Cycle: 1:1
Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1 kg/m^3
Ambient Temperature:22.3 ℃ Liqiud Temperature: 21.5℃
Phantom section: RF Section
DASY4 Configuration:
Probe: H3DV6 - SN6260 ; Calibrated: 10/20/2009
Electronics: DAE4 Sn871; Calibrated: 11/11/2009
Phantom: HAC Test Arch; Type: SD HAC P01 BA;
Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186
H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.443 A/m
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.464 A/m; Power Drift = 0.019 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.391 M4**	Grid 2 **0.408 M4**	Grid 3 **0.384 M4**
Grid 4 **0.427 M4**	Grid 5 **0.443 M4**	Grid 6 **0.414 M4**
Grid 7 **0.397 M4**	Grid 8 **0.410 M4**	Grid 9 **0.381 M4**



0 dB = 0.443A/m

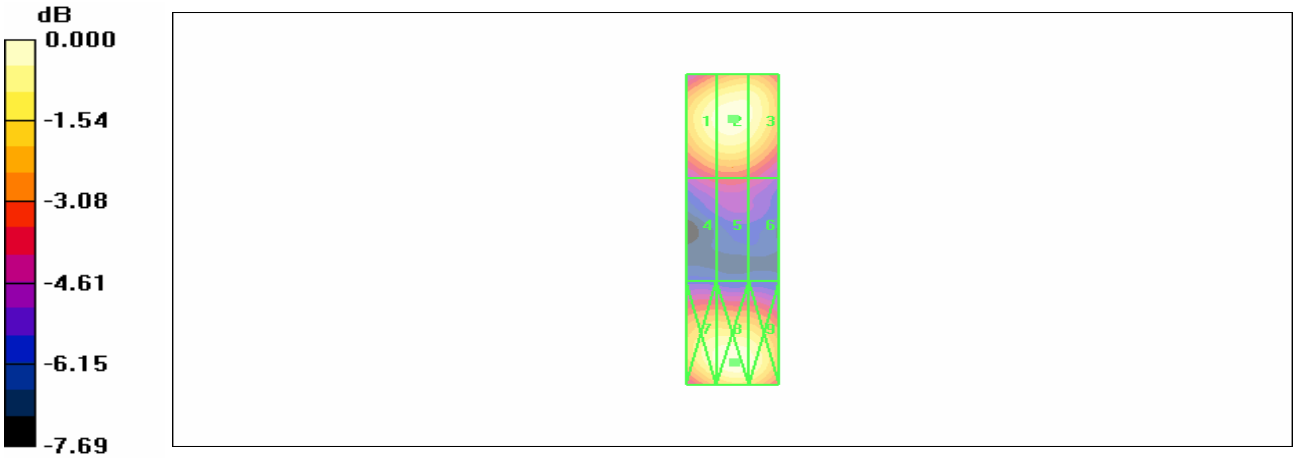
Figure 9 System Performance Check 835MHz_H

HAC_System Performance Check at 1880MHz_E
DUT: Dipole 1880 MHz; Type: CD1880V3; SN:1135
Date/Time: 6/22/2010 1:46:34 AM
Communication System: CW; Frequency: 1880 MHz;Duty Cycle: 1:1
Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1000 kg/m^3
Ambient Temperature:22.3 ℃ Liqiud Temperature: 21.5℃
Phantom section: RF Section
DASY4 Configuration:
Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009
Electronics: DAE4 Sn871; Calibrated: 11/11/2009
Phantom: HAC Test Arch; Type: SD HAC P01 BA;
Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 131.4 V/m
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 151.0 V/m; Power Drift = -0.047 dB
Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **128.5 M2**	Grid 2 **131.4 M2**	Grid 3 **128.5 M2**
Grid 4 **87.5 M3**	Grid 5 **89.7 M3**	Grid 6 **86.2 M3**
Grid 7 **128.7 M2**	Grid 8 **134.0 M2**	Grid 9 **130.3 M2**



0 dB = 134.0V/m

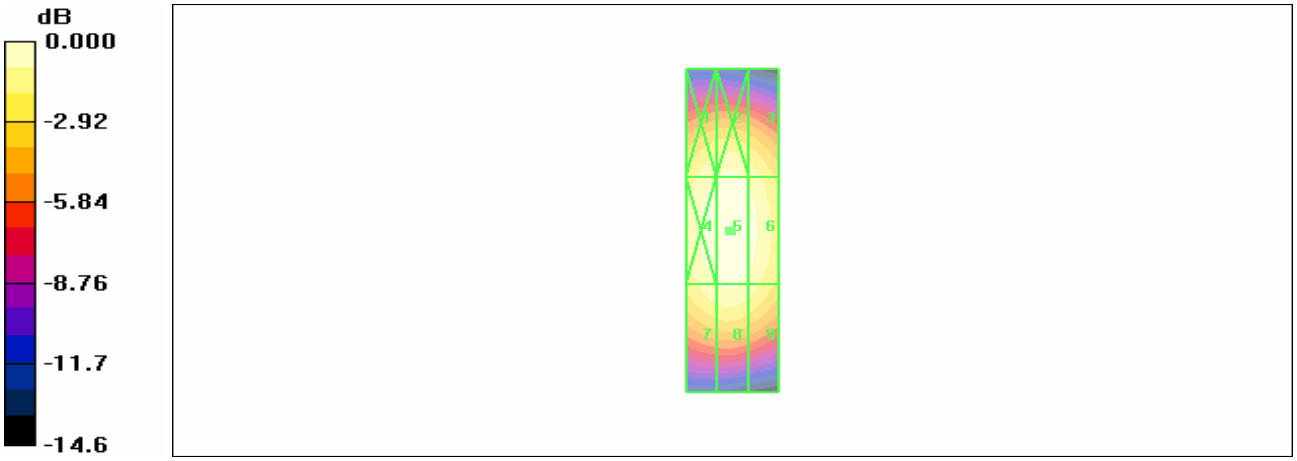
Figure 10 System Performance Check 1880MHz_E

HAC_System Performance Check at 1880MHz_H
DUT: Dipole 1880 MHz; Type: CD1880V3; SN:1135
Date/Time: 6/22/2010 12:49:22 AM
Communication System: CW; Frequency: 1880 MHz;Duty Cycle: 1:1
Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1 kg/m^3
Ambient Temperature:22.3 ℃ Liqiud Temperature: 21.5℃
Phantom section: RF Section
DASY4 Configuration:
Probe: H3DV6 - SN6260; Calibrated: 10/20/2009
Electronics: DAE4 Sn871; Calibrated: 11/11/2009
Phantom: HAC Test Arch; Type: SD HAC P01 BA;
Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.449 A/m
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.472 A/m; Power Drift = -0.005 dB
Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.400 M2**	Grid 2 **0.413 M2**	Grid 3 **0.387 M2**
Grid 4 **0.435 M2**	Grid 5 **0.449 M2**	Grid 6 **0.422 M2**
Grid 7 **0.397 M2**	Grid 8 **0.410 M2**	Grid 9 **0.384 M2**



0 dB = 0.449A/m

Figure 11 System Performance Check 1880MHz_H

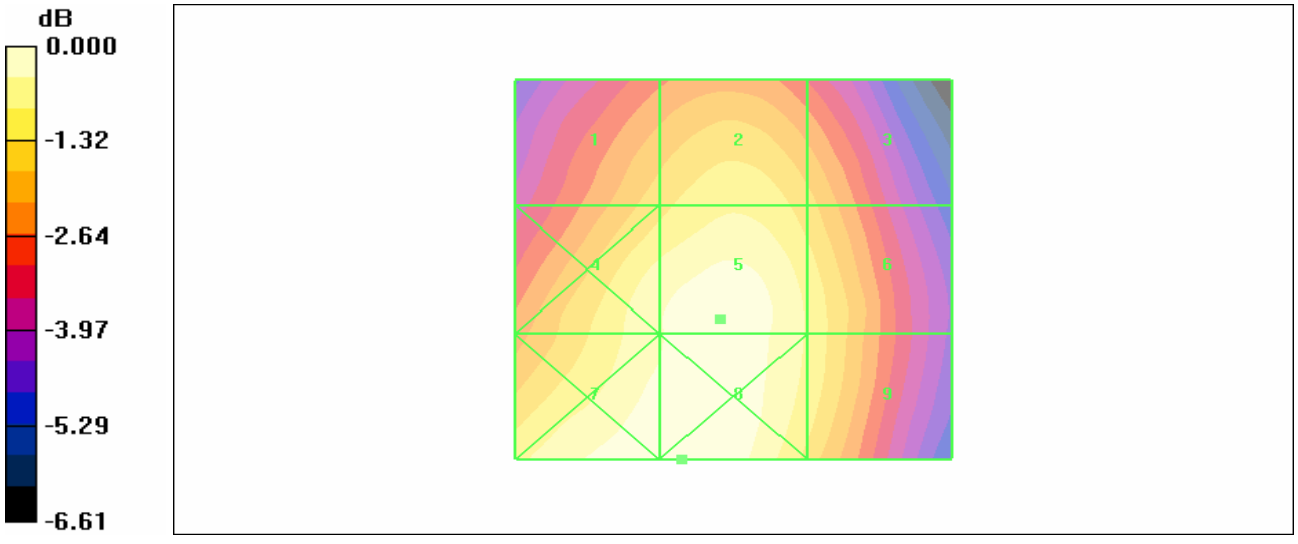
ANNEX B: Graph Results

HAC RF E-Field CDMA Cellular High

Date/Time: 6/22/2010 3:27:05 AM
Communication System: CDMA Cellular; Frequency: 848.31 MHz;Duty Cycle: 1:1
Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1000 kg/m^3
Ambient Temperature:22.3 ℃ Liqiud Temperature: 21.5℃
Phantom section: RF Section
DASY4 Configuration:
Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009
Electronics: DAE4 Sn871; Calibrated: 11/11/2009
Phantom: HAC Test Arch; Type: SD HAC P01 BA;
Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186
E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 77.5 V/m
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 98.3 V/m; Power Drift = -0.001 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **66.6 M4**	Grid 2 **70.9 M4**	Grid 3 **65.8 M4**
Grid 4 **74.8 M4**	Grid 5 **77.5 M4**	Grid 6 **70.8 M4**
Grid 7 **78.5 M4**	Grid 8 **78.9 M4**	Grid 9 **70.8 M4**



0 dB = 78.9V/m

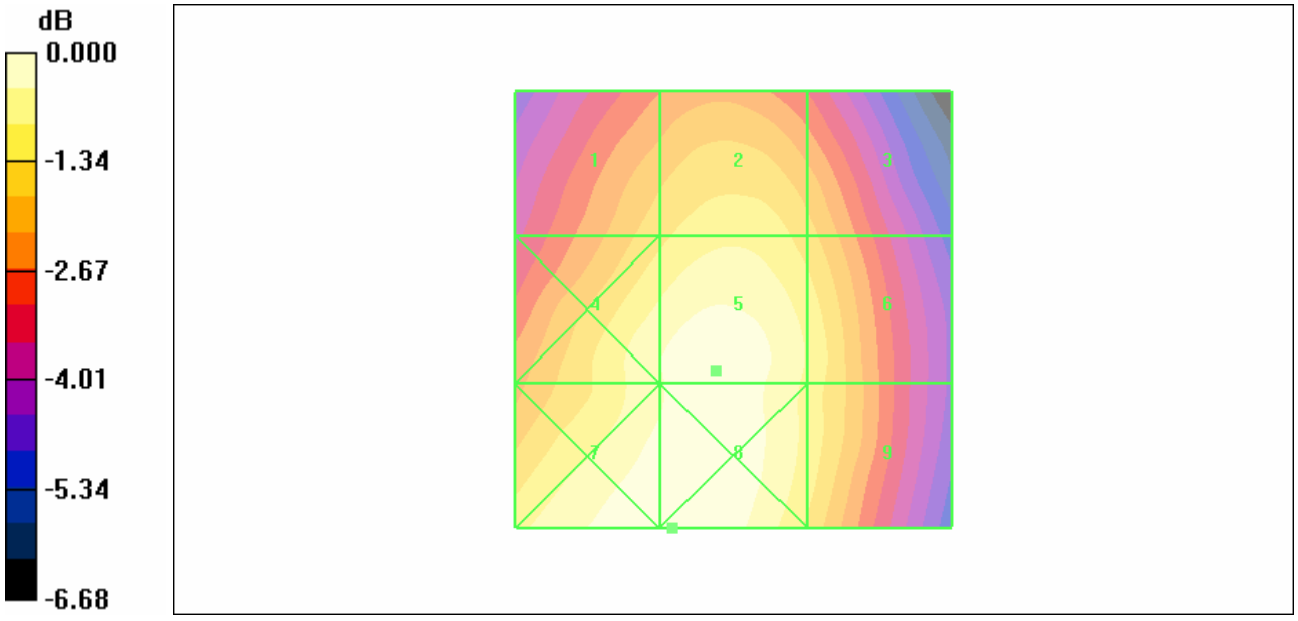
Figure 12 HAC RF E-Field CDMA Cellular Channel 777

HAC RF E-Field CDMA Cellular Middle

Date/Time: 6/22/2010 3:31:48 AM
Communication System: CDMA Cellular; Frequency: 836.52 MHz;Duty Cycle: 1:1
Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1000 kg/m^3
Ambient Temperature:22.3 ℃ Liqiud Temperature: 21.5℃
Phantom section: RF Section
DASY4 Configuration:
Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009
Electronics: DAE4 Sn871; Calibrated: 11/11/2009
Phantom: HAC Test Arch; Type: SD HAC P01 BA;
Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186
E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 72.1 V/m
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 91.4 V/m; Power Drift = -0.010 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **62.1 M4**	Grid 2 **65.5 M4**	Grid 3 **61.2 M4**
Grid 4 **69.8 M4**	Grid 5 **72.1 M4**	Grid 6 **66.1 M4**
Grid 7 **73.4 M4**	Grid 8 **73.5 M4**	Grid 9 **65.4 M4**



0 dB = 73.5V/m

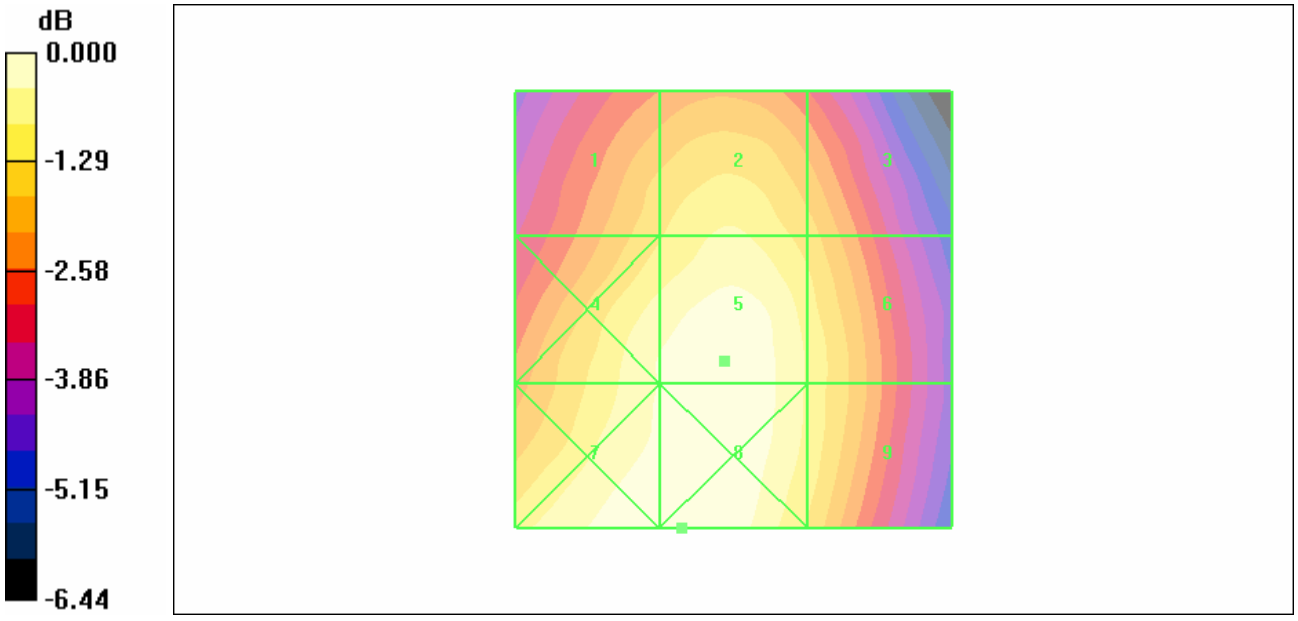
Figure 13 HAC RF E-Field CDMA Cellular Channel 384

HAC RF E-Field CDMA Cellular Low

Date/Time: 6/22/2010 3:36:40 AM
Communication System: CDMA Cellular; Frequency: 824.7 MHz;Duty Cycle: 1:1
Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1000 kg/m^3
Ambient Temperature:22.3 ℃ Liqiud Temperature: 21.5℃
Phantom section: RF Section
DASY4 Configuration:
Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009
Electronics: DAE4 Sn871; Calibrated: 11/11/2009
Phantom: HAC Test Arch; Type: SD HAC P01 BA;
Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186
E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 62.4 V/m
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 79.4 V/m; Power Drift = -0.004 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **54.1 M4**	Grid 2 **57.6 M4**	Grid 3 **53.1 M4**
Grid 4 **60.2 M4**	Grid 5 **62.4 M4**	Grid 6 **56.9 M4**
Grid 7 **62.7 M4**	Grid 8 **63.1 M4**	Grid 9 **56.7 M4**



0 dB = 63.1V/m

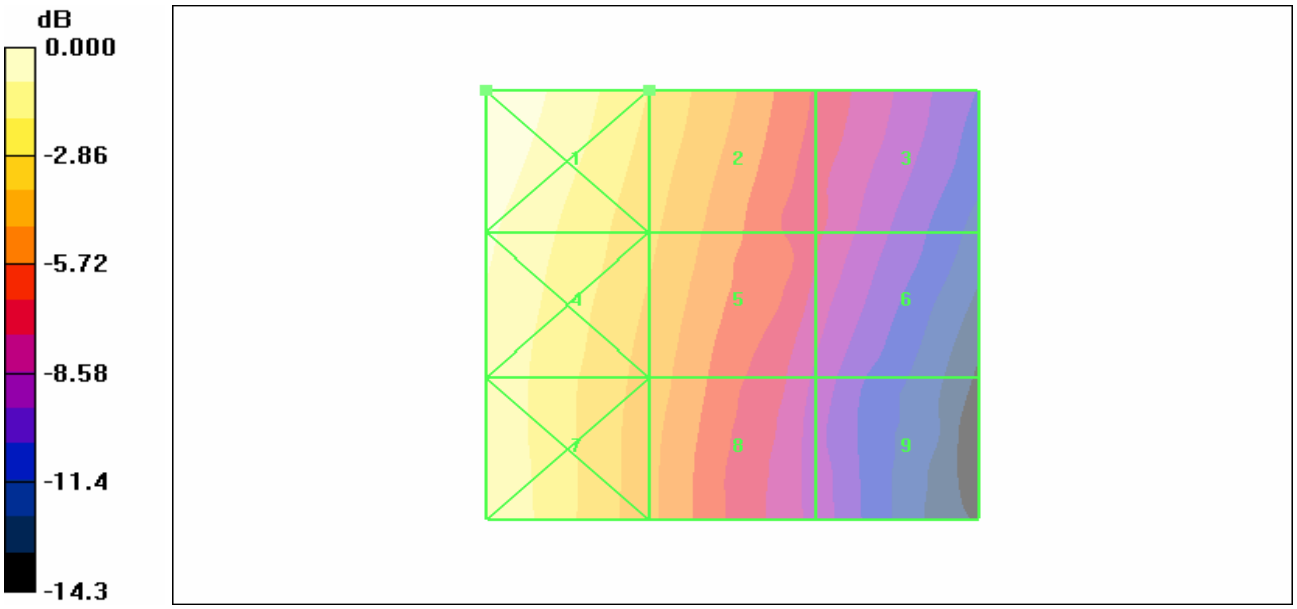
Figure 14 HAC RF E-Field CDMA Cellular Channel 1013

HAC RF H-Field CDMA Cellular High

Date/Time: 6/22/2010 5:17:13 AM
Communication System: CDMA Cellular; Frequency: 848.31 MHz;Duty Cycle: 1:1
Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1 kg/m^3
Ambient Temperature:22.3 ℃ Liqiud Temperature: 21.5℃
Phantom section: RF Section
DASY4 Configuration:
Probe: H3DV6 - SN6260; Calibrated: 10/20/2009
Electronics: DAE4 Sn871; Calibrated: 11/11/2009
Phantom: HAC Test Arch; Type: SD HAC P01 BA;
Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186
H Scan - H3DV6: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.116 A/m
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.085 A/m; Power Drift = 0.055 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.162 M4**	Grid 2 **0.116 M4**	Grid 3 **0.074 M4**
Grid 4 **0.148 M4**	Grid 5 **0.107 M4**	Grid 6 **0.069 M4**
Grid 7 **0.143 M4**	Grid 8 **0.099 M4**	Grid 9 **0.059 M4**



0 dB = 0.162A/m

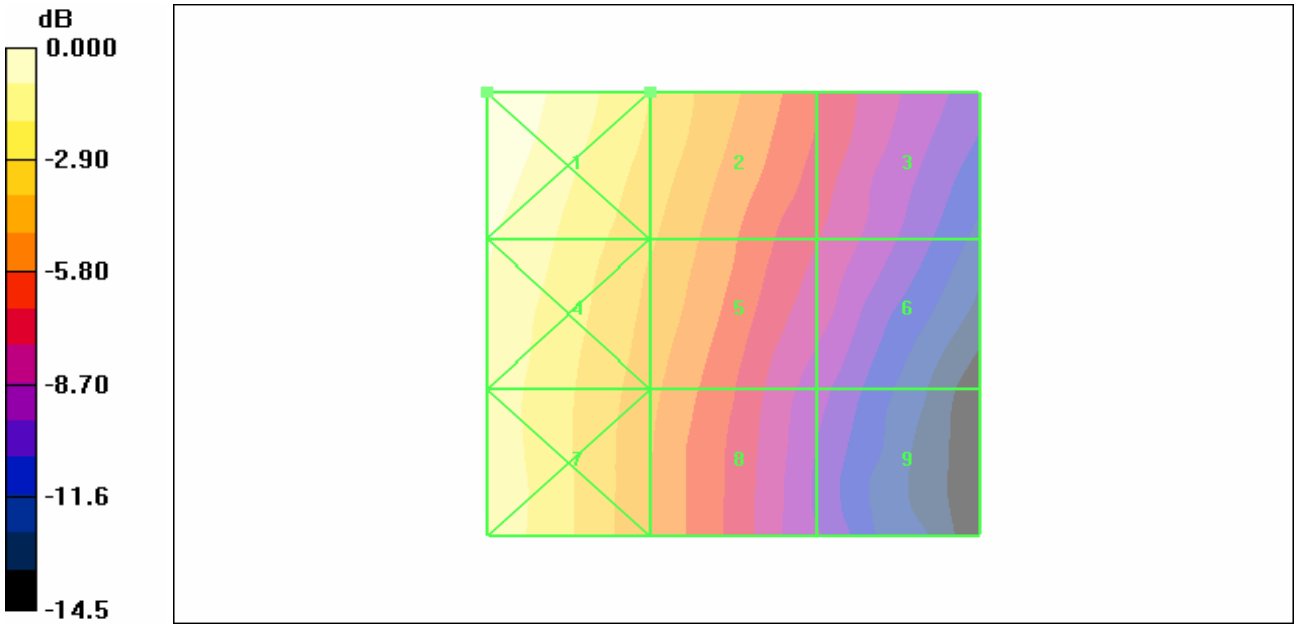
Figure 15 HAC RF H-Field CDMA Cellular Channel 777

HAC RF H-Field CDMA Cellular Middle

Date/Time: 6/22/2010 5:12:30 AM
Communication System: CDMA Cellular; Frequency: 836.52 MHz;Duty Cycle: 1:1
Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1 kg/m^3
Ambient Temperature:22.3 ℃ Liqiud Temperature: 21.5℃
Phantom section: RF Section
DASY4 Configuration:
Probe: H3DV6 - SN6260; Calibrated: 10/20/2009
Electronics: DAE4 Sn871; Calibrated: 11/11/2009
Phantom: HAC Test Arch; Type: SD HAC P01 BA;
Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186
H Scan - H3DV6: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.107 A/m
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.077 A/m; Power Drift = -0.055 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.149 M4**	Grid 2 **0.107 M4**	Grid 3 **0.069 M4**
Grid 4 **0.135 M4**	Grid 5 **0.097 M4**	Grid 6 **0.062 M4**
Grid 7 **0.130 M4**	Grid 8 **0.089 M4**	Grid 9 **0.052 M4**



0 dB = 0.149A/m

Figure 16 HAC RF H-Field CDMA Cellular Channel 384

HAC RF H-Field CDMA Cellular Low

Date/Time: 6/22/2010 5:07:42 AM

Communication System: CDMA Cellular; Frequency: 824.7 MHz;Duty Cycle: 1:1

Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1 kg/m^3

Ambient Temperature:22.3 ℃ Liqiud Temperature: 21.5℃

Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.090 A/m

Probe Modulation Factor = 1.00

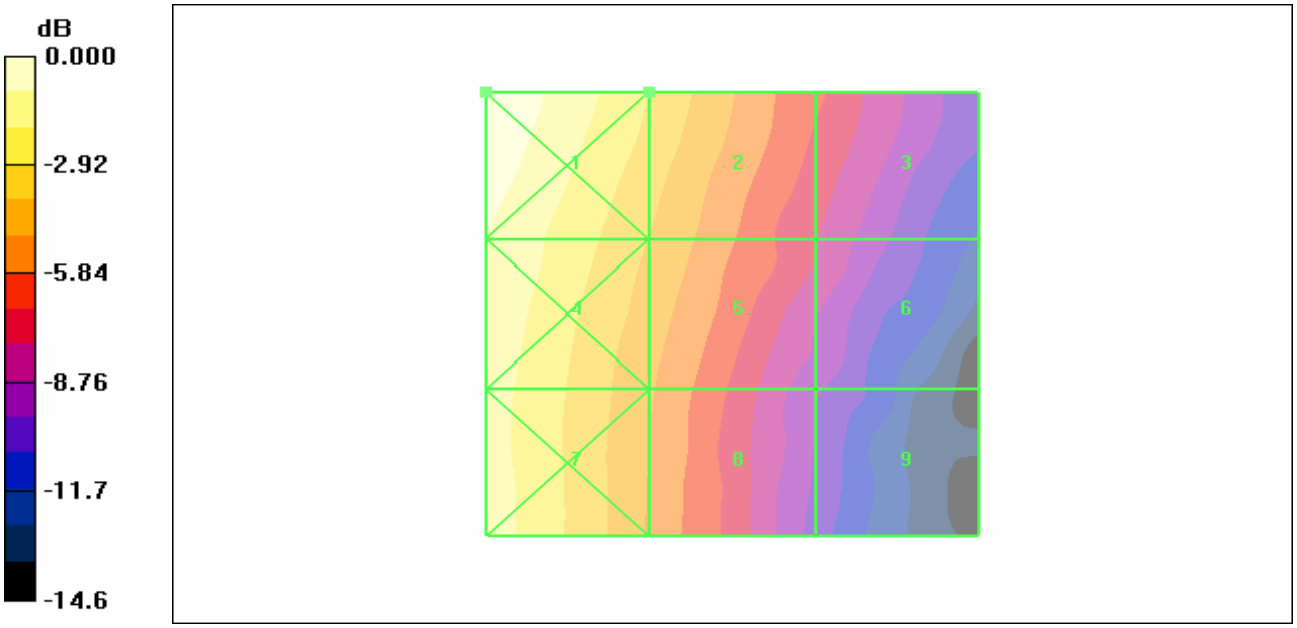
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.063 A/m; Power Drift = 0.133 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.126 M4**	Grid 2 **0.090 M4**	Grid 3 **0.059 M4**
Grid 4 **0.113 M4**	Grid 5 **0.080 M4**	Grid 6 **0.052 M4**
Grid 7 **0.108 M4**	Grid 8 **0.073 M4**	Grid 9 **0.042 M4**



0 dB = 0.126A/m

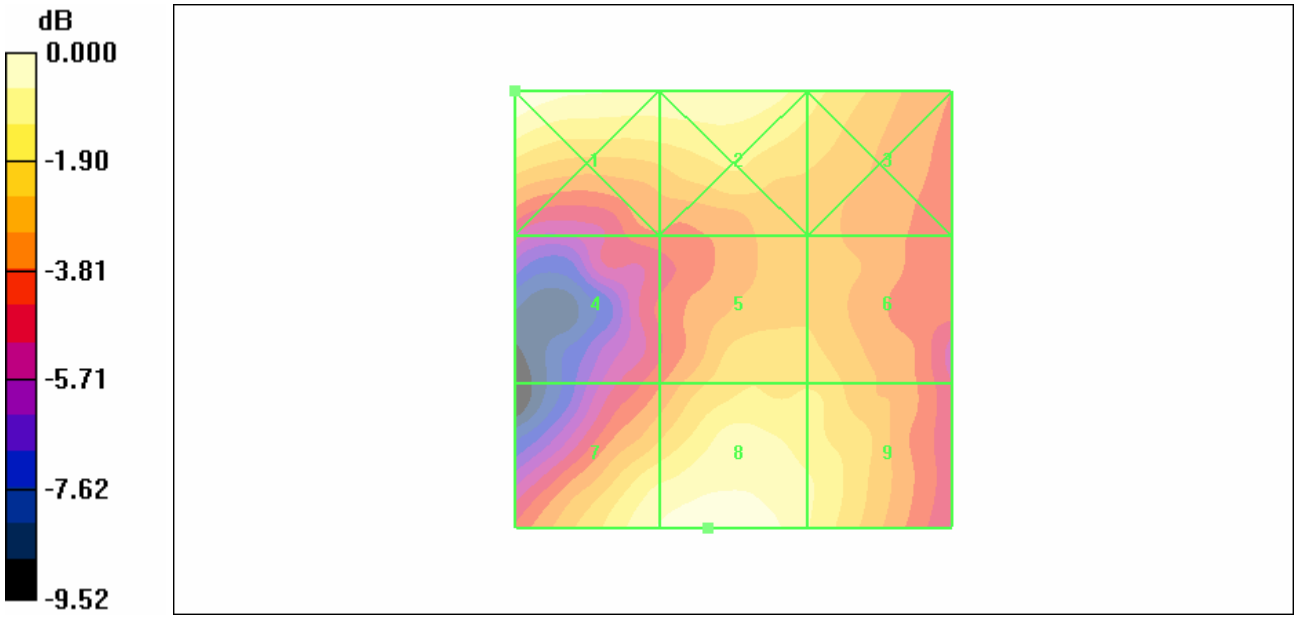
Figure 17 HAC RF H-Field CDMA Cellular Channel 1013

HAC RF E-Field CDMA PCS High

Date/Time: 6/22/2010 2:56:58 AM
Communication System: CDMA PCS; Frequency: 1908.75 MHz;Duty Cycle: 1:1
Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1000 kg/m^3
Ambient Temperature:22.3 ℃ Liqiud Temperature: 21.5℃
Phantom section: RF Section
DASY4 Configuration:
Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009
Electronics: DAE4 Sn871; Calibrated: 11/11/2009
Phantom: HAC Test Arch; Type: SD HAC P01 BA;
Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186
E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 23.8 V/m
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 21.0 V/m; Power Drift = -0.122 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **24.3 M4**	Grid 2 **22.6 M4**	Grid 3 **20.2 M4**
Grid 4 **15.5 M4**	Grid 5 **19.5 M4**	Grid 6 **19.4 M4**
Grid 7 **22.7 M4**	Grid 8 **23.8 M4**	Grid 9 **21.3 M4**



0 dB = 24.3V/m

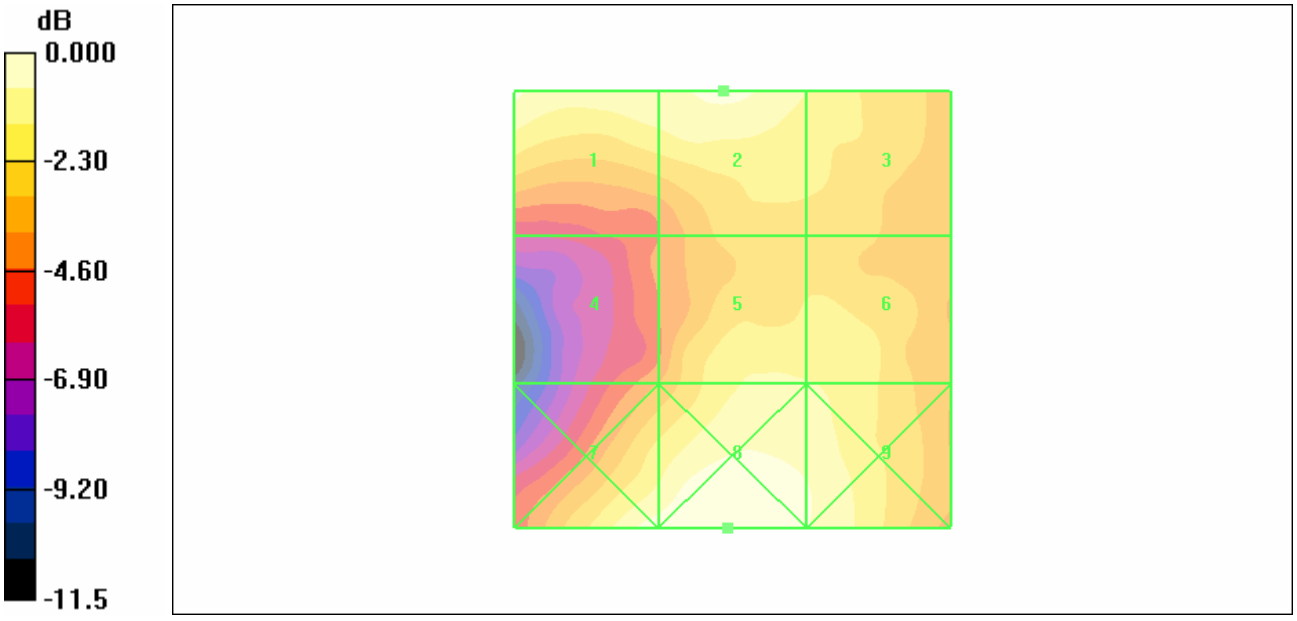
Figure 18 HAC RF E-Field CDMA PCS Channel 1175

HAC RF E-Field CDMA PCS Middle

Date/Time: 6/22/2010 3:02:04 AM
Communication System: CDMA PCS; Frequency: 1880 MHz;Duty Cycle: 1:1
Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1000 kg/m^3
Ambient Temperature:22.3 ℃ Liqiud Temperature: 21.5℃
Phantom section: RF Section
DASY4 Configuration:
Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009
Electronics: DAE4 Sn871; Calibrated: 11/11/2009
Phantom: HAC Test Arch; Type: SD HAC P01 BA;
Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186
E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 21.7 V/m
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 20.7 V/m; Power Drift = -0.125 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **21.6 M4**	Grid 2 **21.7 M4**	Grid 3 **19.4 M4**
Grid 4 **14.9 M4**	Grid 5 **19.5 M4**	Grid 6 **19.4 M4**
Grid 7 **22.1 M4**	Grid 8 **23.0 M4**	Grid 9 **21.3 M4**



0 dB = 23.0V/m

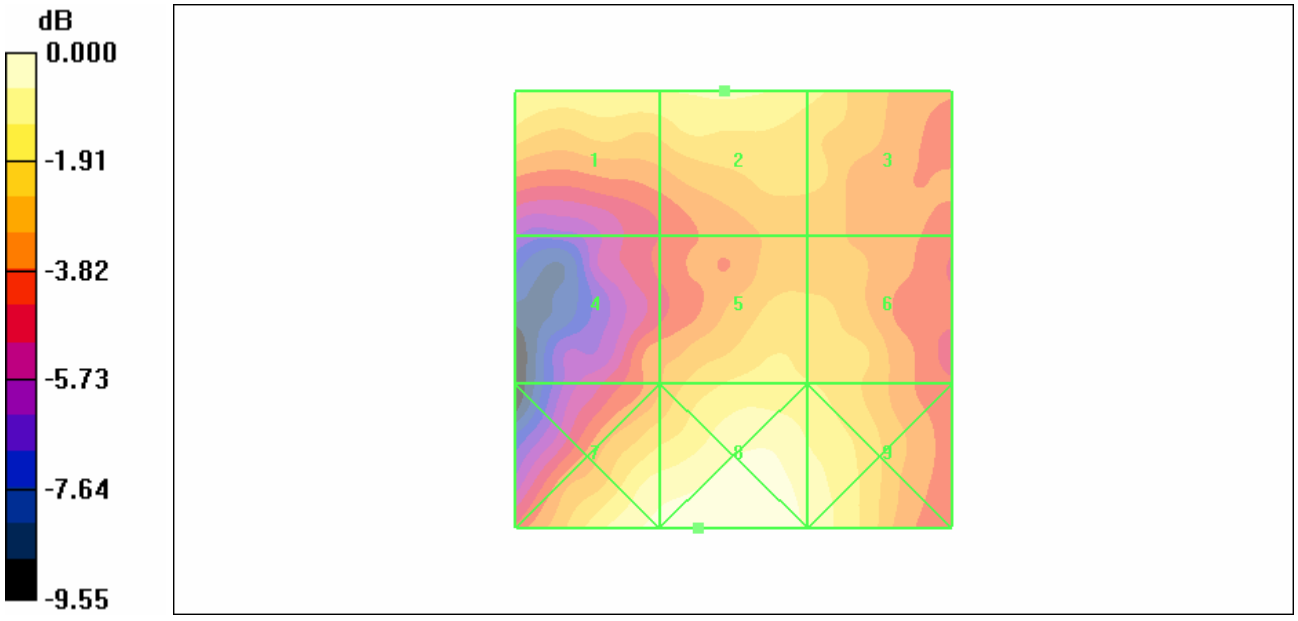
Figure 19 HAC RF E-Field CDMA PCS Channel 600

HAC RF E-Field CDMA PCS Low

Date/Time: 6/22/2010 3:06:56 AM
Communication System: CDMA PCS; Frequency: 1851.25 MHz;Duty Cycle: 1:1
Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1000 kg/m^3
Ambient Temperature:22.3 ℃ Liqiud Temperature: 21.5℃
Phantom section: RF Section
DASY4 Configuration:
Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009
Electronics: DAE4 Sn871; Calibrated: 11/11/2009
Phantom: HAC Test Arch; Type: SD HAC P01 BA;
Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186
E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 20.3 V/m
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 20.6 V/m; Power Drift = -0.012 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **20.2 M4**	Grid 2 **20.3 M4**	Grid 3 **19.1 M4**
Grid 4 **15.9 M4**	Grid 5 **19.1 M4**	Grid 6 **18.7 M4**
Grid 7 **22.1 M4**	Grid 8 **23.1 M4**	Grid 9 **21.2 M4**



0 dB = 23.1V/m

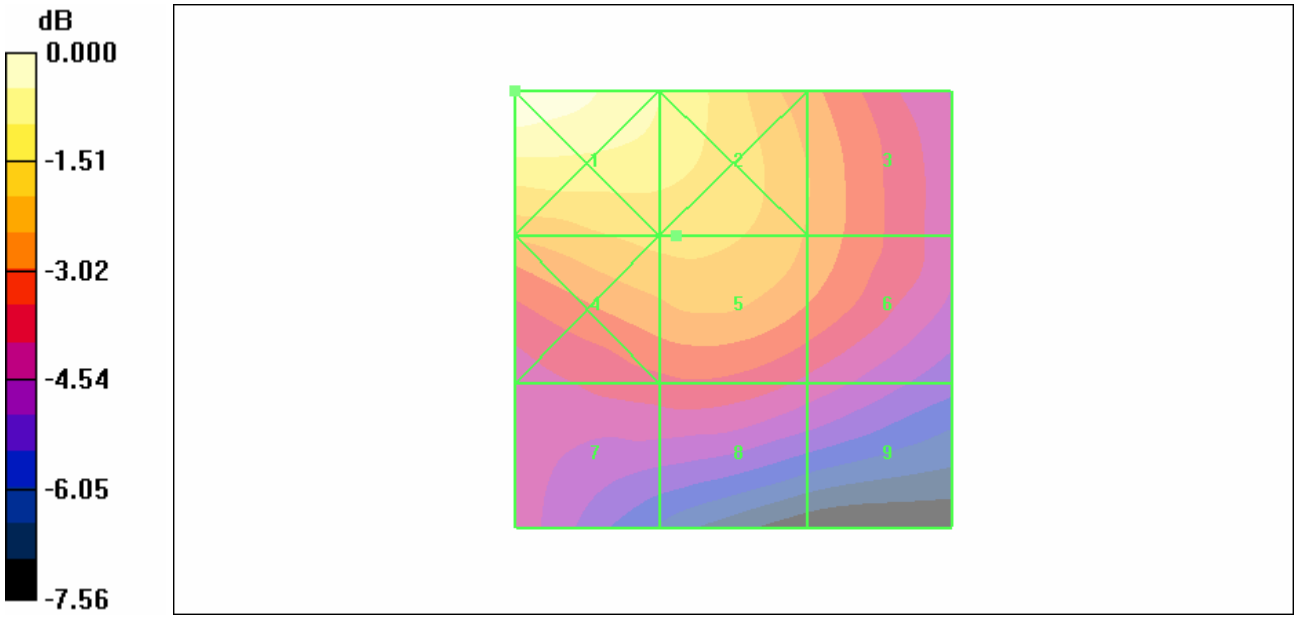
Figure 20 HAC RF E-Field CDMA PCS Channel 25

HAC RF H-Field CDMA PCS High

Date/Time: 6/22/2010 5:43:16 AM
Communication System: CDMA PCS; Frequency: 1908.75 MHz;Duty Cycle: 1:1
Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1 kg/m^3
Ambient Temperature:22.3 ℃ Liqiud Temperature: 21.5℃
Phantom section: RF Section
DASY4 Configuration:
Probe: H3DV6 - SN6260; Calibrated: 10/20/2009
Electronics: DAE4 Sn871; Calibrated: 11/11/2009
Phantom: HAC Test Arch; Type: SD HAC P01 BA;
Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186
H Scan - H3DV6: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.060 A/m
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.063 A/m; Power Drift = -0.054 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.075 M4**	Grid 2 **0.067 M4**	Grid 3 **0.056 M4**
Grid 4 **0.060 M4**	Grid 5 **0.060 M4**	Grid 6 **0.056 M4**
Grid 7 **0.049 M4**	Grid 8 **0.050 M4**	Grid 9 **0.046 M4**



0 dB = 0.075A/m

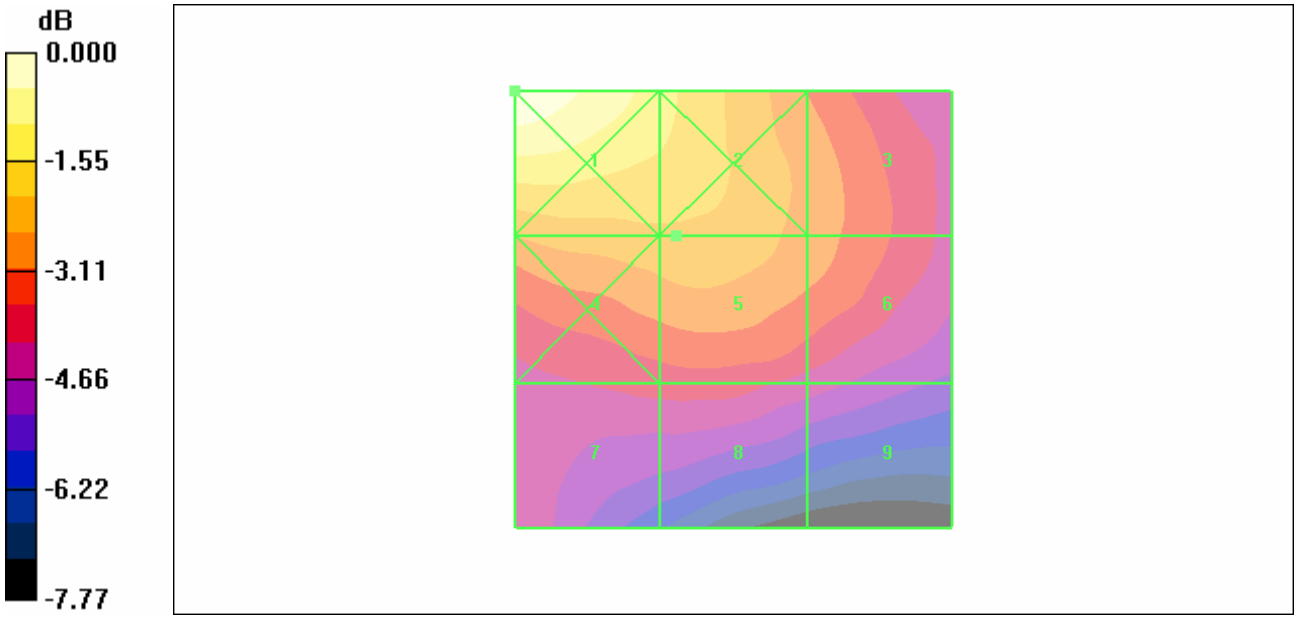
Figure 21 HAC RF H-Field CDMA PCS Channel 1175

HAC RF H-Field CDMA PCS Middle

Date/Time: 6/22/2010 5:38:14 AM
Communication System: CDMA PCS; Frequency: 1880 MHz;Duty Cycle: 1:1
Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1 kg/m^3
Ambient Temperature:22.3 ℃ Liqiud Temperature: 21.5℃
Phantom section: RF Section
DASY4 Configuration:
Probe: H3DV6 - SN6260; Calibrated: 10/20/2009
Electronics: DAE4 Sn871; Calibrated: 11/11/2009
Phantom: HAC Test Arch; Type: SD HAC P01 BA;
Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186
H Scan - H3DV6: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.063 A/m
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.067 A/m; Power Drift = -0.161 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.081 M4**	Grid 2 **0.070 M4**	Grid 3 **0.059 M4**
Grid 4 **0.063 M4**	Grid 5 **0.063 M4**	Grid 6 **0.059 M4**
Grid 7 **0.052 M4**	Grid 8 **0.052 M4**	Grid 9 **0.049 M4**



0 dB = 0.081A/m

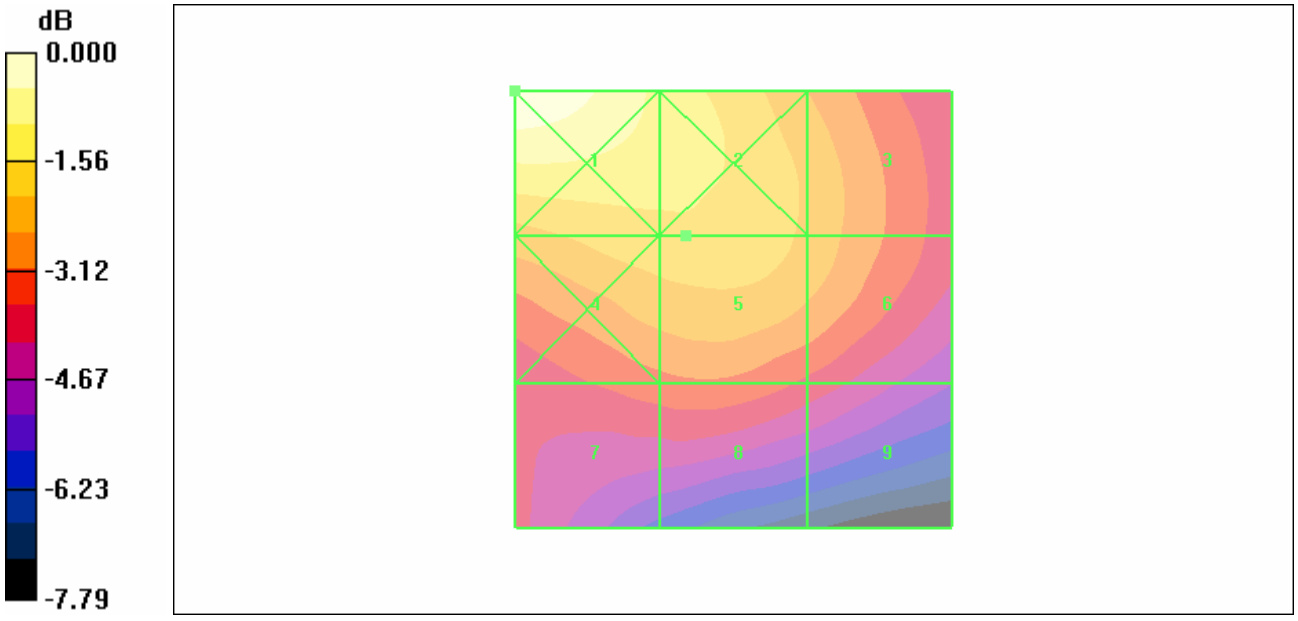
Figure 22 HAC RF H-Field CDMA PCS Channel 600

HAC RF H-Field CDMA PCS Low

Date/Time: 6/22/2010 5:33:22 AM
Communication System: CDMA PCS; Frequency: 1851.25 MHz;Duty Cycle: 1:1
Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1 kg/m^3
Ambient Temperature:22.3 ℃ Liqiud Temperature: 21.5℃
Phantom section: RF Section
DASY4 Configuration:
Probe: H3DV6 - SN6260; Calibrated: 10/20/2009
Electronics: DAE4 Sn871; Calibrated: 11/11/2009
Phantom: HAC Test Arch; Type: SD HAC P01 BA;
Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186
H Scan - H3DV6: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.065 A/m
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.069 A/m; Power Drift = 0.092 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.079 M4**	Grid 2 **0.069 M4**	Grid 3 **0.062 M4**
Grid 4 **0.065 M4**	Grid 5 **0.065 M4**	Grid 6 **0.061 M4**
Grid 7 **0.054 M4**	Grid 8 **0.055 M4**	Grid 9 **0.051 M4**



0 dB = 0.079A/m

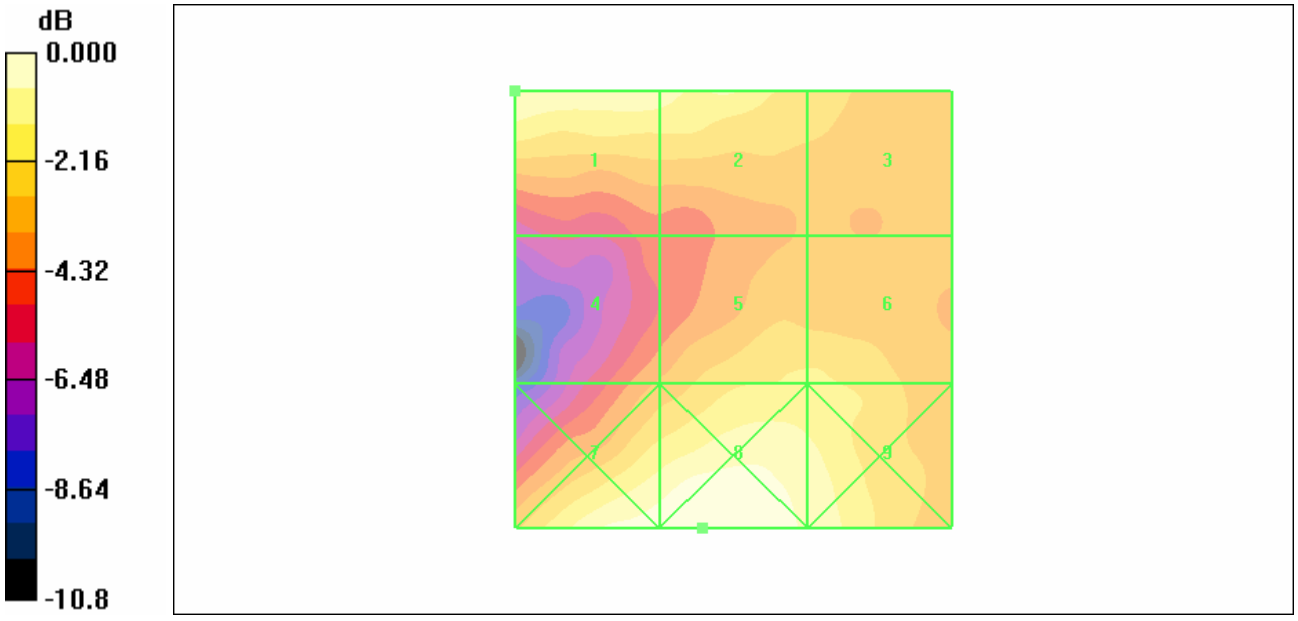
Figure 23 HAC RF H-Field CDMA PCS Channel 25

HAC RF E-Field CDMA AWS High

Date/Time: 6/22/2010 3:12:21 AM
Communication System: CDMA AWS; Frequency: 1752.5 MHz;Duty Cycle: 1:1
Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1000 kg/m^3
Ambient Temperature:22.3 ℃ Liqiud Temperature: 21.5℃
Phantom section: RF Section
DASY4 Configuration:
Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009
Electronics: DAE4 Sn871; Calibrated: 11/11/2009
Phantom: HAC Test Arch; Type: SD HAC P01 BA;
Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186
E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 22.0 V/m
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 18.1 V/m; Power Drift = 0.041 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **22.0 M4**	Grid 2 **21.3 M4**	Grid 3 **18.2 M4**
Grid 4 **16.0 M4**	Grid 5 **18.8 M4**	Grid 6 **18.8 M4**
Grid 7 **23.0 M4**	Grid 8 **23.8 M4**	Grid 9 **21.7 M4**



0 dB = 23.8V/m

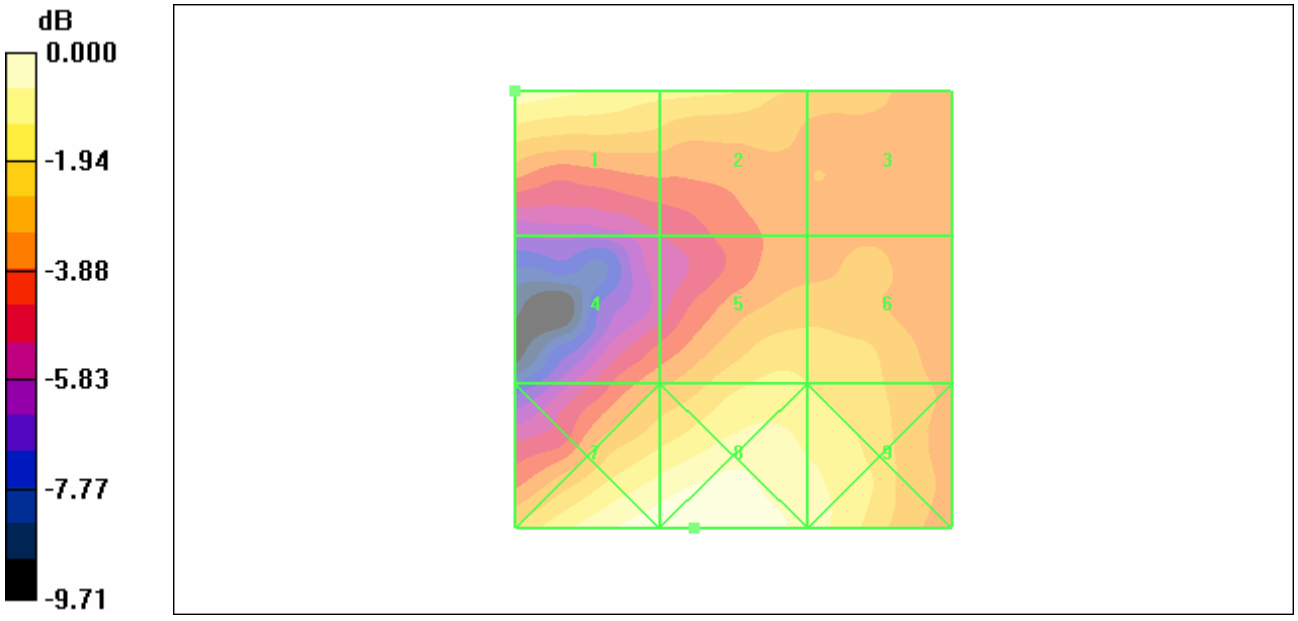
Figure 24 HAC RF E-Field CDMA AWS Channel 850

HAC RF E-Field CDMA AWS Middle

Date/Time: 6/22/2010 3:17:16 AM
Communication System: CDMA AWS; Frequency: 1732.5 MHz;Duty Cycle: 1:1
Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1000 kg/m^3
Ambient Temperature:22.3 ℃ Liqiud Temperature: 21.5℃
Phantom section: RF Section
DASY4 Configuration:
Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009
Electronics: DAE4 Sn871; Calibrated: 11/11/2009
Phantom: HAC Test Arch; Type: SD HAC P01 BA;
Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186
E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 24.4 V/m
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 21.0 V/m; Power Drift = -0.005 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **24.4 M4**	Grid 2 **22.1 M4**	Grid 3 **19.9 M4**
Grid 4 **18.2 M4**	Grid 5 **22.0 M4**	Grid 6 **21.5 M4**
Grid 7 **26.4 M4**	Grid 8 **26.9 M4**	Grid 9 **24.3 M4**



0 dB = 26.9V/m

Figure 25 HAC RF E-Field CDMA AWS Channel 450

HAC RF E-Field CDMA AWS Low

Date/Time: 6/22/2010 3:22:03 AM

Communication System: CDMA AWS; Frequency: 1711.25 MHz;Duty Cycle: 1:1

Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1000 kg/m^3

Ambient Temperature:22.3 ℃ Liqiud Temperature: 21.5℃

Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D: 15 mm from Probe Center to the Device /Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 25.5 V/m

Probe Modulation Factor = 1.00

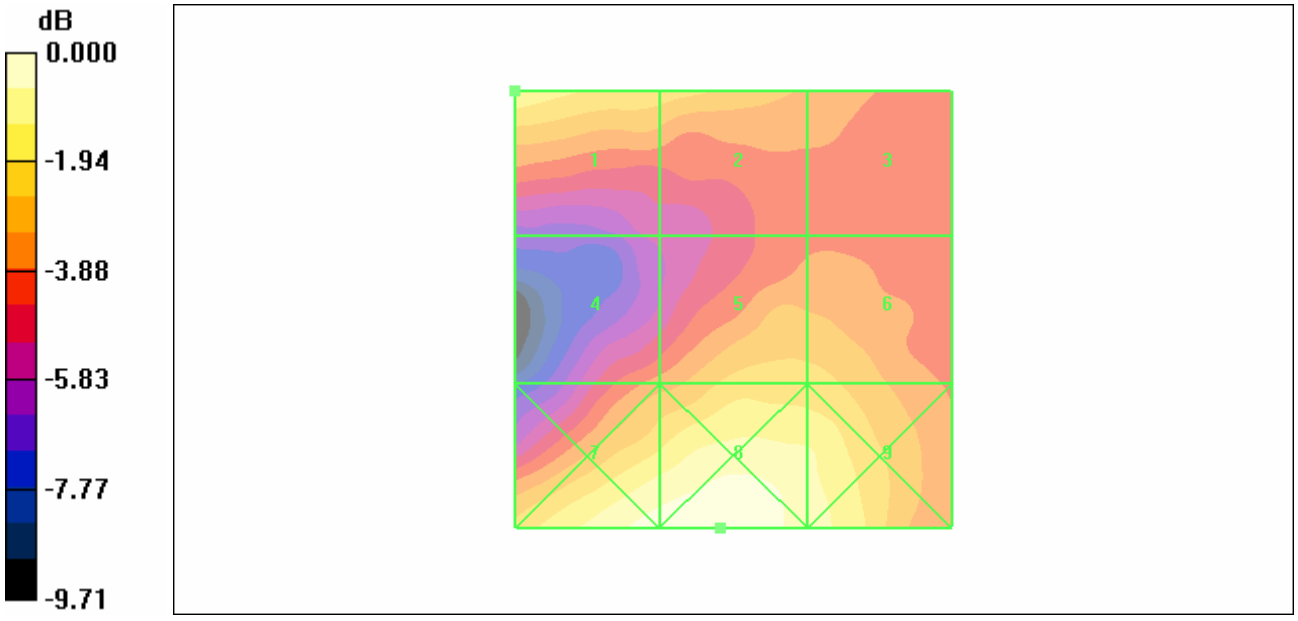
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 21.6 V/m; Power Drift = 0.061 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **25.5 M4**	Grid 2 **23.4 M4**	Grid 3 **20.4 M4**
Grid 4 **19.8 M4**	Grid 5 **23.0 M4**	Grid 6 **22.9 M4**
Grid 7 **28.8 M4**	Grid 8 **29.8 M4**	Grid 9 **26.8 M4**



0 dB = 29.8V/m

Figure 26 HAC RF E-Field CDMA AWS Channel 25

HAC RF H-Field CDMA AWS High

Date/Time: 6/22/2010 5:27:01 AM

Communication System: CDMA AWS; Frequency: 1752.5 MHz;Duty Cycle: 1:1

Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1 kg/m^3

Ambient Temperature:22.3 ℃ Liqiud Temperature: 21.5℃

Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.063 A/m

Probe Modulation Factor = 1.00

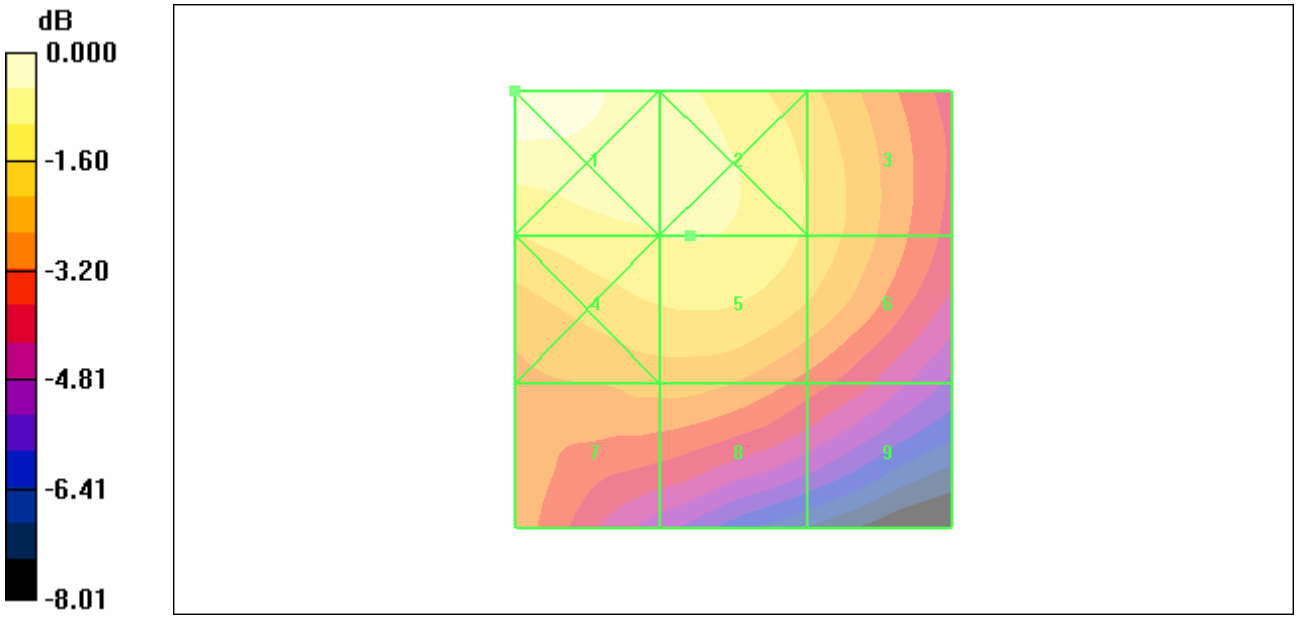
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.067 A/m; Power Drift = -0.009 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.071 M4**	Grid 2 **0.065 M4**	Grid 3 **0.059 M4**
Grid 4 **0.063 M4**	Grid 5 **0.063 M4**	Grid 6 **0.058 M4**
Grid 7 **0.053 M4**	Grid 8 **0.054 M4**	Grid 9 **0.048 M4**



0 dB = 0.071A/m

Figure 27 HAC RF H-Field CDMA AWS Channel 850

HAC RF H-Field CDMA AWS Middle

Date/Time: 6/22/2010 5:22:13 AM

Communication System: CDMA AWS; Frequency: 1732.5 MHz;Duty Cycle: 1:1

Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1 kg/m^3

Ambient Temperature:22.3 ℃ Liqiud Temperature: 21.5℃

Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.071 A/m

Probe Modulation Factor = 1.00

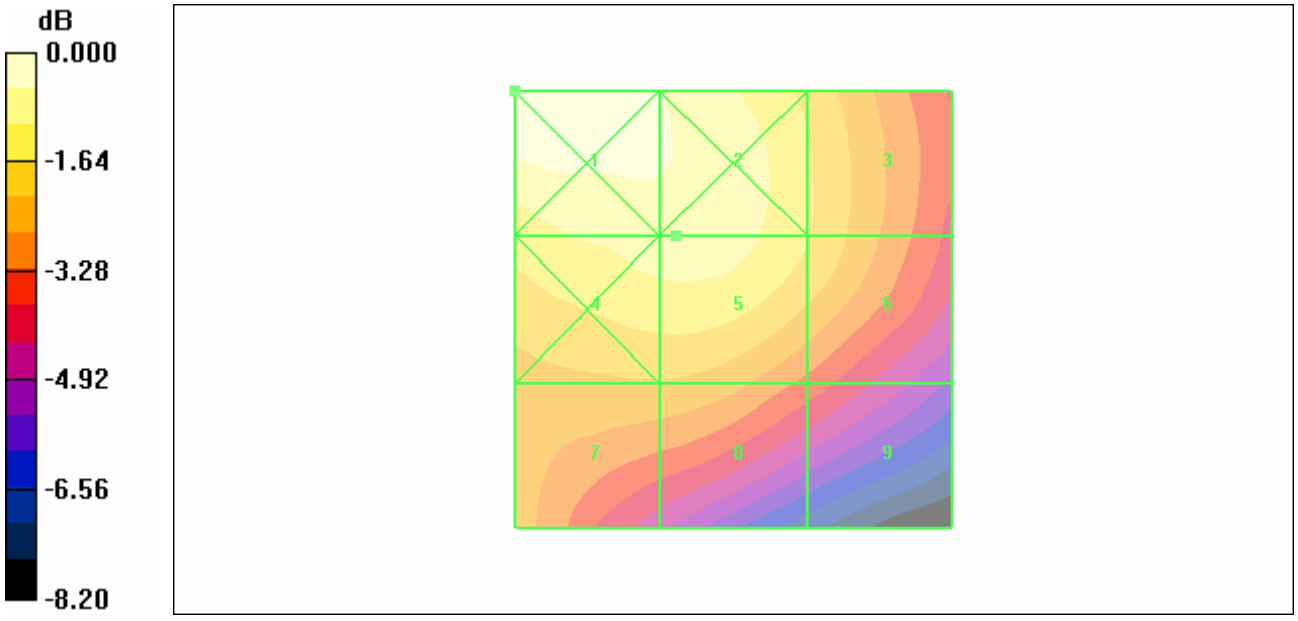
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.073 A/m; Power Drift = -0.012 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.078 M4**	Grid 2 **0.074 M4**	Grid 3 **0.065 M4**
Grid 4 **0.071 M4**	Grid 5 **0.071 M4**	Grid 6 **0.065 M4**
Grid 7 **0.060 M4**	Grid 8 **0.060 M4**	Grid 9 **0.052 M4**



0 dB = 0.078A/m

Figure 28 HAC RF H-Field CDMA AWS Channel 450

HAC RF H-Field CDMA AWS Low

Date/Time: 6/22/2010 4:47:08 AM

Communication System: CDMA AWS; Frequency: 1711.25 MHz;Duty Cycle: 1:1

Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1 kg/m^3

Ambient Temperature:22.3 ℃ Liqiud Temperature: 21.5℃

Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.077 A/m

Probe Modulation Factor = 1.00

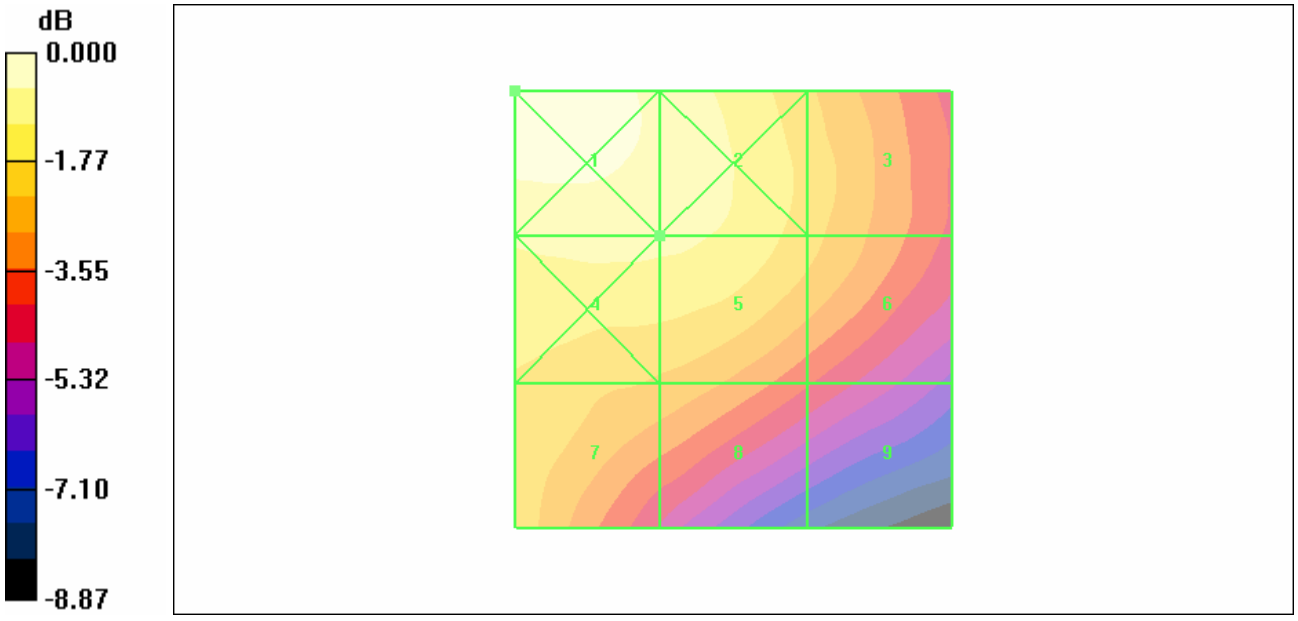
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.078 A/m; Power Drift = -0.132 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.087 M4**	Grid 2 **0.080 M4**	Grid 3 **0.070 M4**
Grid 4 **0.078 M4**	Grid 5 **0.077 M4**	Grid 6 **0.068 M4**
Grid 7 **0.071 M4**	Grid 8 **0.066 M4**	Grid 9 **0.055 M4**



0 dB = 0.087A/m

Figure 29 HAC RF H-Field CDMA AWS Channel 25

ANNEX C: E-Probe Calibration Certificate

Calibration Laboratory of
Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland

S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
S Servizio svizzero di taratura
S Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

Client TMC

Certificate No: ER3-2428_Oct09

CALIBRATION CERTIFICATE

Object ER3DV6 - SN:2428

Calibration procedure(s) QA CAL-02.v5 and QA CAL-25.v2
Calibration procedure for E-field probes optimized for close near field evaluations in air

Calibration date: October 20, 2009

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	1-Apr-09 (No. 217-01030)	Apr-10
Power sensor E4412A	MY41495277	1-Apr-09 (No. 217-01030)	Apr-10
Power sensor E4412A	MY41498087	1-Apr-09 (No. 217-01030)	Apr-10
Reference 3 dB Attenuator	SN: S5054 (3c)	31-Mar-09 (No. 217-01026)	Mar-10
Reference 20 dB Attenuator	SN: S5086 (20b)	31-Mar-09 (No. 217-01028)	Mar-10
Reference 30 dB Attenuator	SN: S5129 (30b)	31-Mar-09 (No. 217-01027)	Mar-10
Reference Probe ER3DV6	SN: 2328	3-Oct-09 (No. ER3-2328_Oct09)	Oct-10
DAE4	SN: 789	19-Dec-08 (No. DAE4-789_Dec08)	Dec-09

Secondary Standards	ID #	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700	4-Aug-99 (in house check Oct-09)	In house check: Oct-11
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-09)	In house check: Oct10

	Name	Function	Signature
Calibrated by:	Marcel Fehr	Laboratory Technician	
Approved by:	Katja Pokovic	Technical Manager	

Issued: October 22, 2009

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

Calibration Laboratory of
Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland

S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
S Servizio svizzero di taratura
S Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

Glossary:

NORMx,y,z	sensitivity in free space
DCP	diode compression point
CF	crest factor (1/duty_cycle) of the RF signal
A, B, C	modulation dependent linearization parameters
Polarization φ	φ rotation around probe axis
Polarization ϑ	ϑ rotation around an axis that is in the plane normal to probe axis (at measurement center), i.e., ϑ = 0 is normal to probe axis
Connector Angle	information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

a) IEEE Std 1309-2005, " IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005.

Methods Applied and Interpretation of Parameters:

- *NORMx,y,z:* Assessed for E-field polarization ϑ = 0 for XY sensors and ϑ = 90 for Z sensor (f ≤ 900 MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- *NORM(f)x,y,z = NORMx,y,z * frequency_response* (see Frequency Response Chart).
- *DCPx,y,z:* DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- *Ax,y,z; Bx,y,z; Cx,y,z* are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media.
- *Spherical isotropy (3D deviation from isotropy)*: in a locally homogeneous field realized using an open waveguide setup.
- *Sensor Offset*: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- *Connector Angle*: The angle is assessed using the information gained by determining the *NORMx* (no uncertainty required).

Probe ER3DV6

SN:2428

Manufactured:	September 11, 2007
Last calibrated:	December 13, 2007
Recalibrated:	October 20, 2009

Calibrated for DASY Systems

(Note: non-compatible with DASY2 system!)

ER3DV6 SN:2428 October 20, 2009

DASY - Parameters of Probe: ER3DV6 SN:2428

Basic Calibration Parameters

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm ($\mu V/(V/m)^2$)	1.52	1.59	1.86	± 10.1%
DCP (mV)[A]	91.5	93.0	98.9	

Modulation Calibration Parameters

UID	Communication System Name	PAR		A dB	B dBuV	C	VR mV	Unc (k=2)
10000	CW		X	0.00	0.00	1.00	300	± 1.5%
			Y	0.00	0.00	1.00	300	
			Z	0.00	0.00	1.00	300	

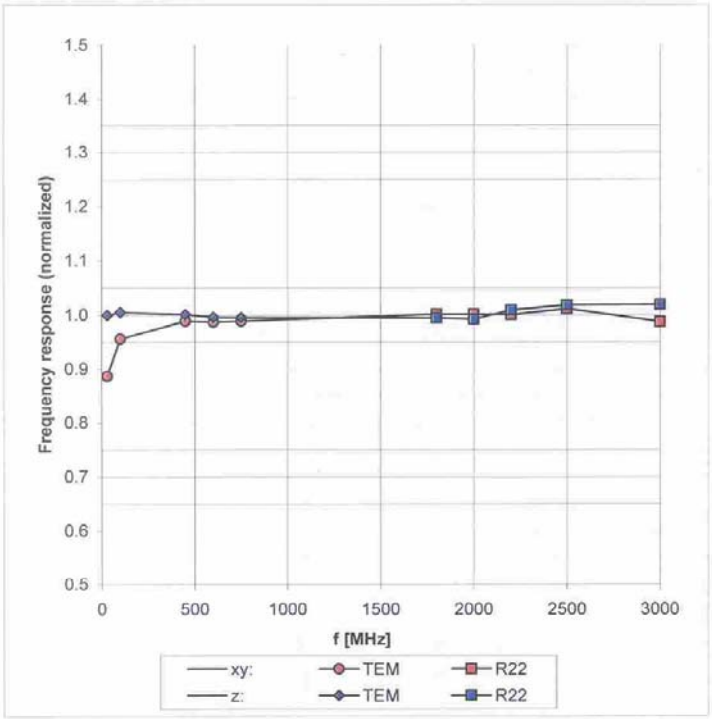
The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

[A] numerical linearization parameter: uncertainty not required

ER3DV6 SN:2428 October 20, 2009

Frequency Response of E-Field

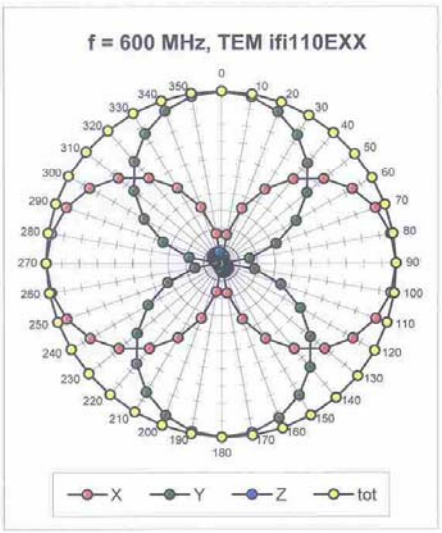
(TEM-Cell:ifi110 EXX, Waveguide R22)

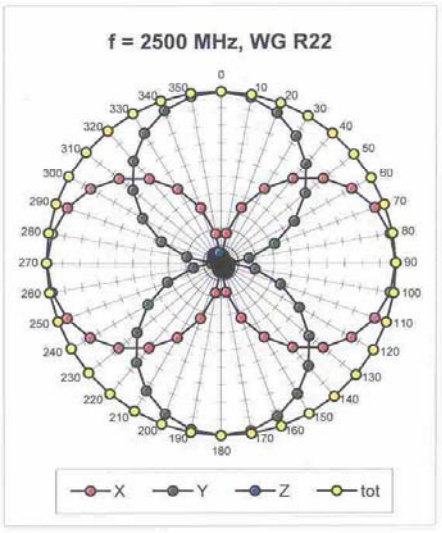


Uncertainty of Frequency Response of E-field: ± 6.3% (k=2)

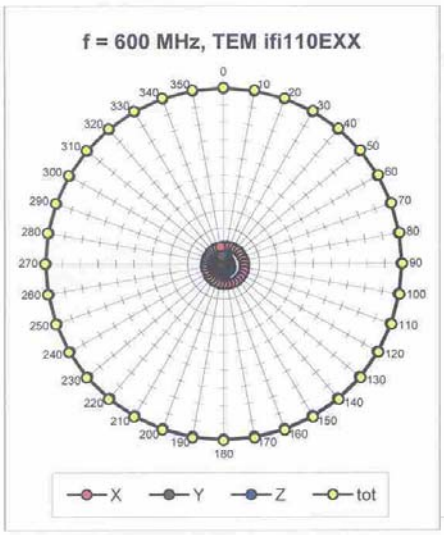
ER3DV6 SN:2428 October 20, 2009

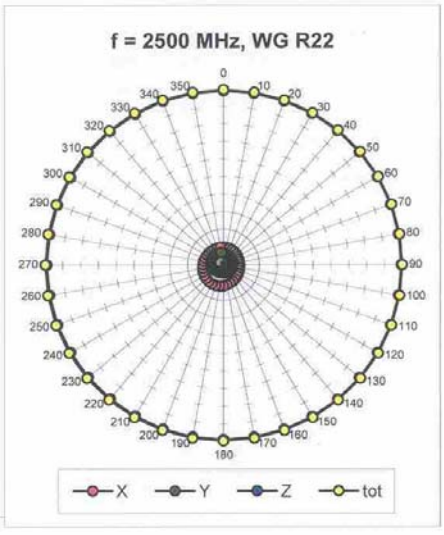
Receiving Pattern (ϕ), ϑ = 0°





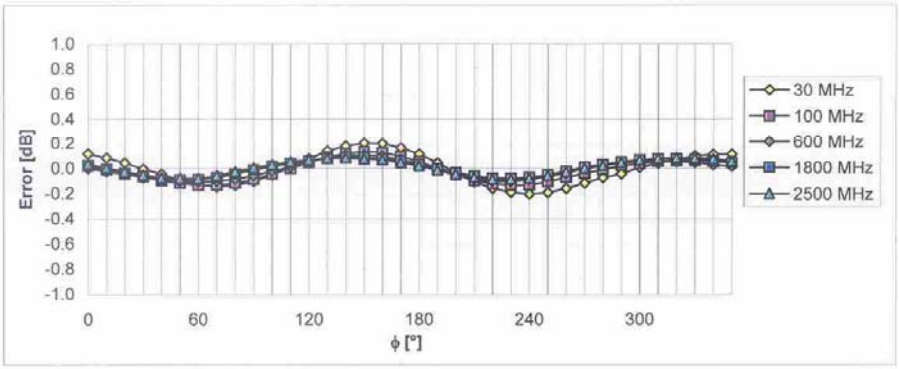
Receiving Pattern (ϕ), ϑ = 90°





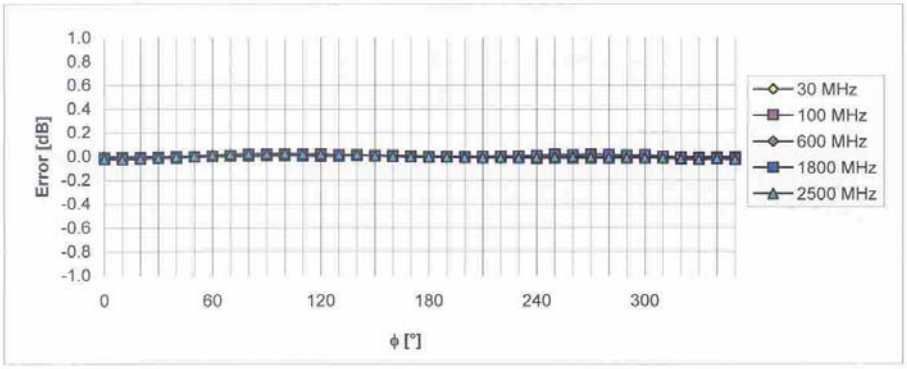
ER3DV6 SN:2428 October 20, 2009

Receiving Pattern (ϕ), ϑ = 0°



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

Receiving Pattern (ϕ), ϑ = 90°



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

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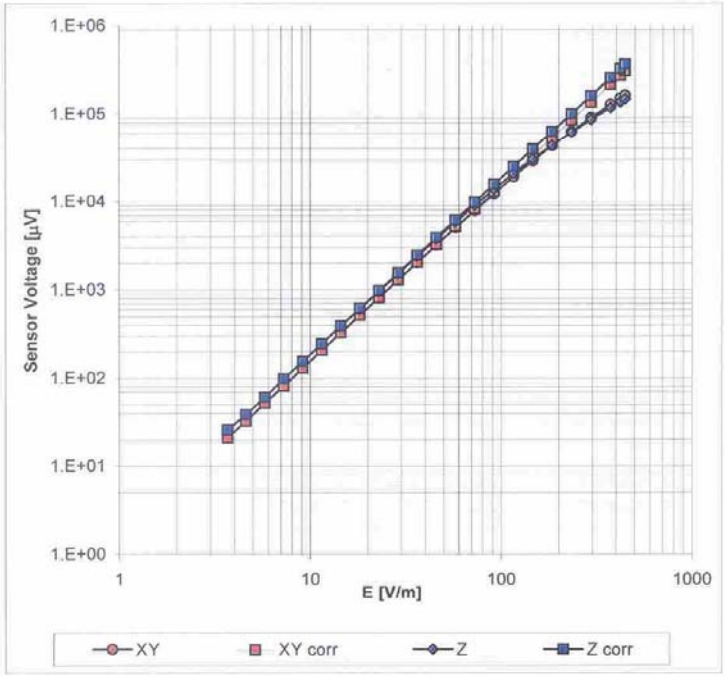
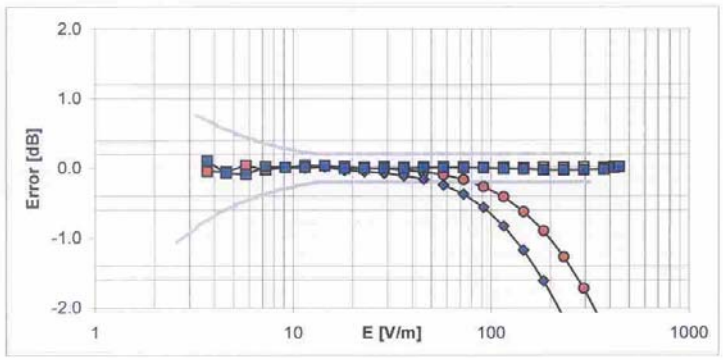
Dynamic Range f(E-field)

(Waveguide R22, f = 1800 MHz)





Uncertainty of Linearity Assessment: ± 0.6% (k=2)

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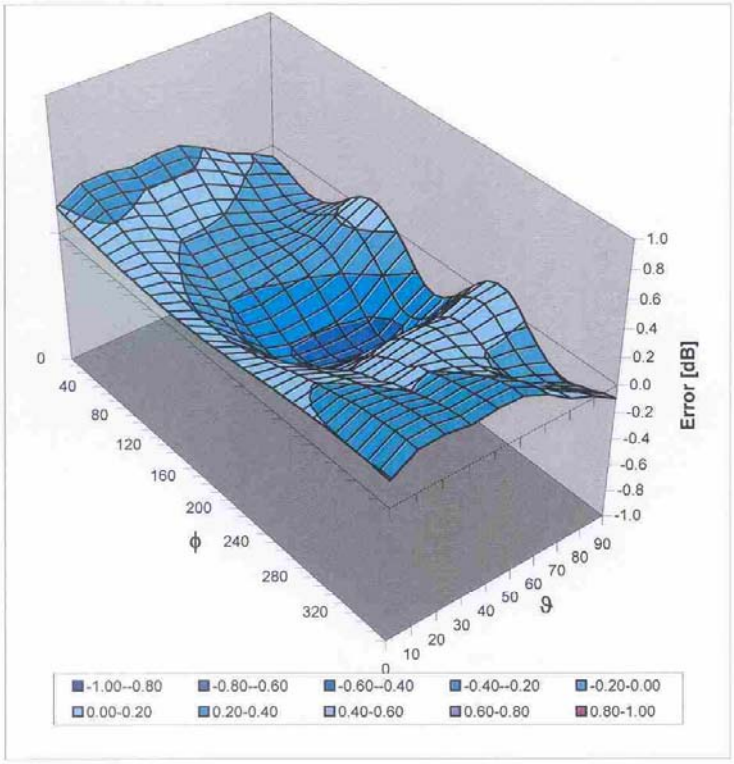
Deviation from Isotropy in Air
Error (ϕ, ϑ), f = 900 MHz



Uncertainty of Spherical Isotropy Assessment: ± 2.6% (k=2)

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Other Probe Parameters

Sensor Arrangement	Rectangular
Connector Angle (°)	-218.7
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	10 mm
Tip Diameter	8.0 mm
Probe Tip to Sensor X Calibration Point	2.5 mm
Probe Tip to Sensor Y Calibration Point	2.5 mm
Probe Tip to Sensor Z Calibration Point	2.5 mm

ANNEX D: H-Probe Calibration Certificate

Calibration Laboratory of
Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland

S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
S Servizio svizzero di taratura
S Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

Client TMC

Certificate No: H3-6260_Oct09

CALIBRATION CERTIFICATE

Object H3DV6 - SN:6260

Calibration procedure(s) QA CAL-03.v5 and QA CAL-25.v2
Calibration procedure for H-field probes optimized for close near field evaluations in air

Calibration date: October 20, 2009

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	1-Apr-09 (No. 217-01030)	Apr-10
Power sensor E4412A	MY41495277	1-Apr-09 (No. 217-01030)	Apr-10
Power sensor E4412A	MY41498087	1-Apr-09 (No. 217-01030)	Apr-10
Reference 3 dB Attenuator	SN: S5054 (3c)	31-Mar-09 (No. 217-01026)	Mar-10
Reference 20 dB Attenuator	SN: S5086 (20b)	31-Mar-09 (No. 217-01028)	Mar-10
Reference 30 dB Attenuator	SN: S5129 (30b)	31-Mar-09 (No. 217-01027)	Mar-10
Reference Probe H3DV6	SN: 6182	3-Oct-09 (No. H3-6182_Oct09)	Oct-10
DAE4	SN: 789	19-Dec-08 (No. DAE4-789_Dec08)	Dec-09

Secondary Standards	ID #	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700	4-Aug-99 (in house check Oct-09)	In house check: Oct-11
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-09)	In house check: Oct10

	Name	Function	Signature
Calibrated by:	Marcel Fehr	Laboratory Technician	
Approved by:	Katja Pokovic	Technical Manager	

Issued: October 22, 2009

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

Calibration Laboratory of
Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland

S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
S Servizio svizzero di taratura
Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

Glossary:

NORMx,y,z	sensitivity in free space
DCP	diode compression point
CF	crest factor (1/duty_cycle) of the RF signal
A, B, C	modulation dependent linearization parameters
Polarization φ	φ rotation around probe axis
Polarization ϑ	ϑ rotation around an axis that is in the plane normal to probe axis (at measurement center), i.e., ϑ = 0 is normal to probe axis
Connector Angle	information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

a) IEEE Std 1309-2005, " IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005.

Methods Applied and Interpretation of Parameters:

- *NORMx,y,z:* Assessed for E-field polarization ϑ = 0 for XY sensors and ϑ = 90 for Z sensor (f ≤ 900 MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- *X,Y,Z(f)_a0a1a2= X,Y,Z_a0a1a2* frequency_response* (see Frequency Response Chart).
- *DCPx,y,z:* DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- *Ax,y,z; Bx,y,z; Cx,y,z* are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media.
- *Spherical isotropy (3D deviation from isotropy)*: in a locally homogeneous field realized using an open waveguide setup.
- *Sensor Offset*: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- *Connector Angle*: The angle is assessed using the information gained by determining the *X_a0a1a2* (no uncertainty required).

Probe H3DV6

SN:6260

Manufactured:	September 7, 2007
Last calibrated:	December 13, 2007
Recalibrated:	October 20, 2009

Calibrated for DASY Systems

(Note: non-compatible with DASY2 system!)

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DASY - Parameters of Probe: H3DV6 SN:6260

Basic Calibration Parameters

		Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm (A/m / √(μV))	a0	2.47E-3	2.49E-3	2.95E-3	± 10.1%
Norm (A/m / √(μV))	a1	-2.97E-5	5.62E-6	-4.47E-5	± 10.1%
Norm (A/m / √(μV))	a2	4.84E-5	4.36E-5	6.01E-5	± 10.1%
DCP (mV)[A]		84.5	90.3	83.9	

Modulation Calibration Parameters

UID	Communication System Name	PAR		A dB	B dBuV	C	VR mV	Unc (k=2)
10000	CW	0.00	X	0.00	0.00	1.00	300	± 1.5%
			Y	0.00	0.00	1.00	300	
			Z	0.00	0.00	1.00	300	

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

[1] numerical linearization parameter: uncertainty not required

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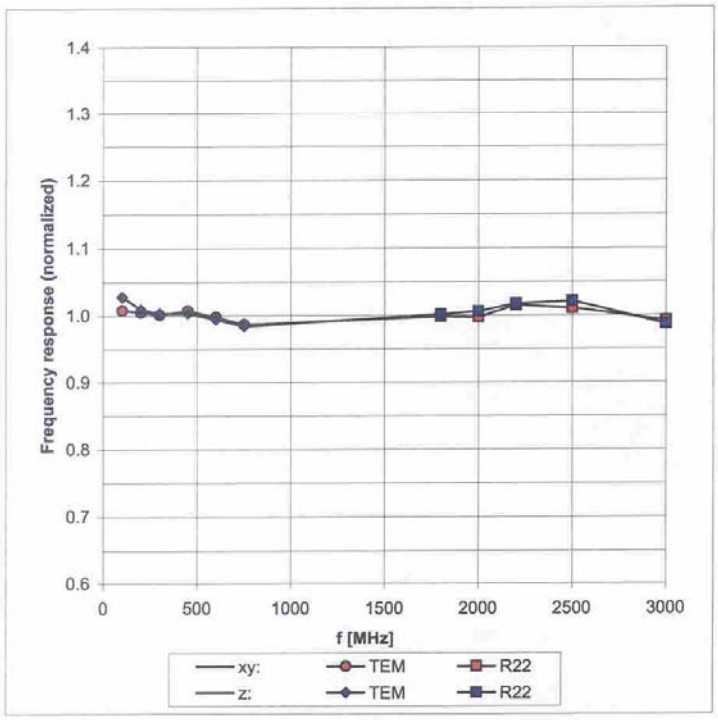
Frequency Response of H-Field

(TEM-Cell:ifi110 EXX, Waveguide R22)



Uncertainty of Frequency Response of H-field: ± 6.3% (k=2)